

TOSHIBA

Selection Guide 2024

Small Signal and Logic Devices








Contents

1. MOSFETs	3-14
■ Over 500mA Series MOSFETs (Semi-Power Type)	
■ Less than 500mA Series MOSFETs (Standard Type)	
■ MOSFET with Diode	
■ Bipolar Transistor with Diode	
■ Part Naming Conventions	
2. Bipolar Transistors	15-19
■ General-Purpose Transistors	
■ Bias Resistor Built-in Transistors (BRTs)	
3. Diodes	20-30
■ Schottky Barrier Diodes (SBDs)	
■ Switching Diodes	
■ TVS Diodes (ESD Protection Diodes)	
■ Zener Diodes for Over Voltage Protection	
■ Part Naming Conventions	
4. Power Management ICs	31-34
■ Low Dropout Regulators (LDO)	
■ Load Switch ICs	
■ N-ch MOSFET Gate driver ICs with OVP function	
■ Power Multiplexer ICs	
■ eFuse ICs	
5. Linear ICs	35-36
■ Thermoflagger™ (Over Temperature Detection IC)	
■ Operational Amplifiers, Comparators	
6. Sensors	37
■ Magnetic Sensors	
7. General Purpose Logic ICs	38-51
7-1 One-Gate Logic ICs (L-MOS)	
7-2 CMOS Logic ICs	
■ Standard Logic 74VHC Series (TSSOP14B / 16B / 20B Package Products)	
■ Standard Logic 74HC Series, 74LCX Series (TSSOP14B / 16B / 20B Package Products)	
■ Standard Logic 74VHC Series (US14 / 16 / 20 Package Products)	
■ Standard Logic 74LCX Series, 74VCX Series (US14 / 16 / 20 Package Products)	
■ Standard Logic 74HC Series, TC4000B Series (SOIC14 / 16 / 20, SOP14 / 16 / 20 Package Products)	
■ Standard Logic TC74VCX Series, TC74LCX Series (TSSOP14 / 16 / 20 / 48 Package Products)	
7-3 Bus Switches	
■ High-Speed Transmission Type	
■ General Purpose Bus Switches	
7-4 Level Shifters	
7-5 Part Naming Conventions	
8. Radio-Frequency Devices	52-54
■ RF Diodes	
■ Part Naming Conventions	
9. Device Packages	55-63

1. MOSFETs

Over 500mA Series MOSFETs (Semi-Power Type)

Package Dimensions (unit: mm)

CST3C	CST3 (SOT-883)	VESM (SOT-723)	UFM (SOT-323F)	ES6 (SOT-563)	UF6 (SOT-363F)	WCSP6C
Bottom View  0.8 x 0.6	Bottom View  1.0 x 0.6	 1.2 x 1.2	 2.0 x 2.1	 1.6 x 1.6	 2.0 x 2.1	Bottom View  1.5 x 1.0

P-Channel Single MOSFET

Package	Part Number	V _{oss} (V)	V _{ess} (V)	I _o (A)	R _{DS(ON)} max (mΩ)						Q _g typ. (nC)	C _{iss} typ. (pF)	Note	
					V _{GS} = -1.2V	V _{GS} = -1.5V	V _{GS} = -1.8V	V _{GS} = -2.5V	V _{GS} = -4V	V _{GS} = -4.5V				V _{GS} = -10V
CST3C	SSM3J64CTC	\$ -12	+/-10	-1	11300	1310	890	560	-	370	-	50		
	SSM3J65CTC	\$ -20	+/-10	-0.7	11300	1550	1070	700	-	500	-	48		
CST3	SSM3J56ACT	\$ -20	+/-8	-1.4	4000	900	660	480	-	390	-	1.6	100	
	SSM3J76CT	★ \$ -20	+/-8	-1.4	4000	900	660	480	-	390	-	1.6	100	Low leakage current
	SSM3J65CT	☆ \$ -20	+/-10	-0.7	11300	1550	1070	700	-	500	-	-	48	
VESM	SSM3J66MFV	# \$ -20	+6/-8	-0.8	4000	900	660	480	-	390	-	1.6	100	
	SSM3J56MFV	\$ -20	+/-8	-0.8	4000	900	660	480	-	390	-	1.6	100	
	SSM3J76MFV	★ \$ -20	+/-8	-0.8	4000	900	660	480	-	390	-	1.6	100	Low leakage current
WCSP6C	SSM6J771G	\$ -20	+/-12	-5	-	-	-	47.5	-	35	34.7 (@-8V) 31 (@-8.5V)	9.8	870	
ES6	SSM6J216FE	\$ -12	+/-8	-4.8	-	88.1	56	39.3	-	32	-	12.7	1040	
	SSM6J213FE	\$ -20	+/-8	-2.6	-	250	178	133	-	103	-	4.7	290	
	SSM6J215FE	\$ -20	+/-8	-3.4	-	154	104	79	-	59	-	10.4	630	
	SSM6J212FE	\$ -20	+/-8	-4	-	94	65.4	49	-	40.7	-	14.1	970	
	SSM6J207FE	\$ -30	+/-20	-1.4	-	-	-	-	491	-	251	-	137	
	SSM6J214FE	\$ -30	+/-12	-3.6	-	-	149.6	77.6	-	57	50	7.9	560	
UFM	SSM3J132TU	\$ -12	+/-6	-5.4	94	39	29	21	-	17	-	33	2700	
	SSM3J135TU	\$ -20	+/-8	-3	-	260	180	132	-	103	-	4.6	270	
	SSM3J145TU	# \$ -20	+6/-8	-3	-	260	180	132	-	103	-	4.6	270	
	SSM3J134TU	\$ -20	+/-8	-3.2	-	240	168	123	-	93	-	4.7	290	
	SSM3J144TU	# \$ -20	+6/-8	-3.2	-	240	168	123	-	93	-	4.7	290	
	SSM3J130TU	\$ -20	+/-8	-4.4	-	63.2	41.1	31	-	25.8	-	24.8	1800	
	SSM3J140TU	# \$ -20	+6/-8	-4.4	-	63.2	41.1	31	-	25.8	-	24.8	1800	
	SSM3J133TU	\$ -20	+/-8	-5.5	-	88.4	56	39.7	-	29.8	-	12.8	840	
	SSM3J143TU	# \$ -20	+6/-8	-5.5	-	88.4	56	39.7	-	29.8	-	12.8	840	
	SSM3J112TU	# \$ -30	+/-20	-1.1	-	-	-	-	790	-	390	-	86	
	SSM3J118TU	# \$ -30	+/-20	-1.4	-	-	-	-	480	-	240	-	137	
SSM3J117TU	# \$ -30	+/-20	-2	-	-	-	-	225	-	117	-	280		
UF6	SSM6J422TU	# \$ -20	+6/-8	-4	-	99.6	67.8	51.4	-	42.7	-	12.8	840	
	SSM6J412TU	\$ -20	+/-8	-4	-	99.6	67.8	51.4	-	42.7	-	12.8	840	
	SSM6J424TU	# \$ -20	+6/-8	-6	-	54	36	26	-	22.5	-	23.1	1650	
	SSM6J414TU	\$ -20	+/-8	-6	-	54	36	26	-	22.5	-	23.1	1650	
	SSM6J402TU	# \$ -30	+/-20	-2	-	-	-	-	225	-	117	5.3	280	
	SSM6J410TU	# \$ -30	+/-20	-2.1	-	-	-	-	393	-	216	2.9	120	
SSM6J401TU	# \$ -30	+/-20	-2.5	-	-	-	-	145	-	73	16	730		








☆ New Products, ★ Under Development (The specification is subject to change without notice.)
AEC-Q101 qualified, \$ With protection Zener diode between gate and source

UDFN6B (SOT-1220)	SOT-23F	S-Mini (SOT-346)	TSOP6F
Bottom View 			
2.0 x 2.0	2.9 x 2.4	2.9 x 2.5	2.9 x 2.8

P-Channel Single MOSFET

Package	Part Number	V _{BS} (V)	V _{GS} (V)	I _D (A)	R _{DS(ON)} max (mΩ)						Q _g typ. (nC)	C _{ISS} typ. (pF)	Note		
					V _{GS} = -1.2 V	V _{GS} = -1.5 V	V _{GS} = -1.8 V	V _{GS} = -2.5 V	V _{GS} = -4 V	V _{GS} = -4.5 V				V _{GS} = -10 V	
UDFN6B	SSM6J512NU	\$	-12	+/-10	-10	-	-	40.1	25.7	20.5 (@-3.6 V)	18.7	16.2 (@-8 V)	19.5	1400	
	SSM6J505NU	\$	-12	+/-6	-12	61	30	21	16	-	12	-	37.6	2700	
	SSM6J511NU	\$	-12	+/-10	-14	-	-	19.2	13.5	11.5 (@-3.6 V)	10	9.1 (@-8 V)	47	3350	
	SSM6J503NU	\$	-20	+/-8	-6	-	89.6	57.9	41.7	-	32.4	-	12.8	840	
	SSM6J502NU	\$	-20	+/-8	-6	-	60.5	38.4	28.3	-	23.1	-	24.8	1800	
	SSM6J501NU	\$	-20	+/-8	-10	-	43	26.5	19	-	15.3	-	29.9	2600	
SSM6J507NU	\$	-30	+20/-25	-10	-	-	-	-	32	28	20	13.6	1150		
SOT-23F	SSM3J338R	\$	-12	+/-10	-6	-	-	45.3	27.9	21.9 (@-3.6 V)	20.2	17.6 (@-8 V)	19.5	1400	
	SSM3J327R	\$	-20	+/-8	-3.9	-	240	168	123	-	93	-	4.6	290	
	SSM3J377R	# \$	-20	+6/-8	-3.9	-	240	168	123	-	93	-	4.6	290	
	SSM3J331R	\$	-20	+/-8	-4	-	150	100	75	-	55	-	10.4	630	
	SSM3J371R	# \$	-20	+6/-8	-4	-	150	100	75	-	55	-	10.4	630	
	SSM3J328R	\$	-20	+/-8	-6	-	88.4	56	39.7	-	29.8	-	12.8	840	
	SSM3J378R	# \$	-20	+6/-8	-6	-	88.4	56	39.7	-	29.8	-	12.8	840	
	SSM3J355R	\$	-20	+/-10	-6	-	-	52.3	38.8	-	30.1	-	16.6	1030	
	SSM3J358R	\$	-20	+/-10	-6	-	-	49.3	32.8	27.7 (@-3.6 V)	25.3	22.1 (@-8 V)	38.5	1331	
	SSM3J334R	\$	-30	+/-20	-4	-	-	-	-	136	105	71	5.9	280	
	SSM3J374R	# \$	-30	+10/-20	-4	-	-	-	-	136	105	71	5.9	280	
	SSM3J340R	\$	-30	+20/-25	-4	-	-	-	-	86	73	45	6.2	492	
	SSM3J332R	\$	-30	+/-12	-6	-	-	144	72	-	50	42	8.2	560	
	SSM3J372R	# \$	-30	+6/-12	-6	-	-	144	72	-	50	42	8.2	560	
	SSM3J356R	# \$	-60	+10/-20	-2	-	-	-	-	400	360	300	8.3	330	
SSM3J351R	# \$	-60	+10/-20	-3.5	-	-	-	-	184	164	134	15.1	660		
S-Mini	SSM3J325F	\$	-20	+/-8	-2	-	311	231	179	-	150	-	4.6	270	
	SSM3J375F	# \$	-20	+6/-8	-2	-	311	231	179	-	150	-	4.6	270	
	SSM3J352F	\$	-20	+/-12	-2	-	-	443	199	-	136	110	5.1	210	
	SSM3J353F	\$	-30	+20/-25	-2	-	-	-	-	274	232	150	3.4	159	
TSOP6F	SSM6J801R	\$	-20	+6/-8	-6	-	88.4	56	39.7	-	32.5	-	12.8	840	
	SSM6J825R	☆ \$	-30	+10/-20	-4	-	-	-	-	86	73	45	6.2	492	
	SSM6J808R	#	-40	+10/-20	-7	-	-	-	-	52	48	35	24.2	1020	

☆ New Products
AEC-Q101 qualified, \$ With protection Zener diode between gate and source

CST3 (SOT-883)	VESM (SOT-723)	SSM (SOT-416)	UFM (SOT-323F)	ES6 (SOT-563)	UF6 (SOT-363F)	WCSP6C
Bottom View 						Bottom View 
1.0 x 0.6	1.2 x 1.2	1.6 x 1.6	2.0 x 2.1	1.6 x 1.6	2.0 x 2.1	1.5 x 1.0

N-Channel Single MOSFET

Package	Part Number	V _{oss} (V)	V _{ess} (V)	I _o (A)	R _{DS(on)} max (mΩ)							Q _g typ. (nC)	C _{iss} typ. (pF)	Note
					V _{GS} = 1.2 V	V _{GS} = 1.5 V	V _{GS} = 1.8 V	V _{GS} = 2.5 V	V _{GS} = 4 V	V _{GS} = 4.5 V	V _{GS} = 10 V			
CST3	SSM3K56CT	\$ 20	+/-8	0.8	-	840	480	300	-	235	-	1	55	
	SSM3K56ACT	\$ 20	+/-8	1.4	-	840	480	300	-	235	-	1	55	
	SSM3K76CT ★	\$ 20	+/-8	1.4	-	840	480	300	-	235	-	1	55	Low leakage current
VESM	SSM3K36MFV #	\$ 20	+/-10	0.5	-	1520	1140	850	-	660	630 (@5 V)	1.23	46	
	SSM3K56MFV	\$ 20	+/-8	0.8	-	840	480	300	-	235	-	1	55	
	SSM3K76MFV ★	\$ 20	+/-8	0.8	-	840	480	300	-	235	-	1	55	Low leakage current
WCSP6C	SSM6K781G	12	+/-8	7	-	124	47.4	23.2	-	18	-	5.4	600	
SSM	SSM3K36FS #	\$ 20	+/-10	0.5	-	1520	1140	850	-	660	630 (@5 V)	1.23	46	
	SSM3K56FS	\$ 20	+/-8	0.8	-	840	480	300	-	235	-	1	55	
	SSM3K76FS ★	\$ 20	+/-8	0.8	-	840	480	300	-	235	-	1	55	Low leakage current
ES6	SSM6K217FE	\$ 40	+/-12	1.8	-	-	400	248	218 (@3.6 V) 211 (@4.2 V)	208	195 (@8 V)	1.1	130	
UFM	SSM3K36TU #	\$ 20	+/-10	0.5	-	1520	1140	850	-	660	630 (@5 V)	1.23	46	
	SSM3K62TU #	\$ 20	+/-8	0.8	432	139	89	68	-	57	-	2	177	
	SSM3K122TU #	\$ 20	+/-10	2	-	304	211	161	123	-	-	3.4	195	
	SSM3K121TU #	\$ 20	+/-10	3.2	-	140	93	63	48	-	-	5.9	400	
	SSM3K123TU #	\$ 20	+/-10	4.2	-	66	43	32	28	-	-	13.6	1010	
	SSM3K127TU #	\$ 30	+/-12	2	-	-	286	167	123	-	-	1.5	123	
	SSM3K116TU #	\$ 30	+/-12	2.2	-	-	-	135	-	100	-	-	245	
	SSM3K131TU #	\$ 30	+/-20	6	-	-	-	-	-	41.5	27.6	10.1	450	
	SSM3H137TU #	\$ 34	+/-20	2	-	-	-	-	295	280	240	3	119	Built-in Active Clamp Zener
	SSM3K2615TU #	\$ 60	+/-20	2	-	-	-	580 (@3.3 V)	440	-	300	6	150	
	SSM3K341TU #	\$ 60	+/-20	6	-	-	-	-	69	51	36	9.3	550	T _{ch} = 175 °C
SSM3K361TU #	\$ 100	+/-20	3.5	-	-	-	-	-	92	69	3.2	430	T _{ch} = 175 °C	
UF6	SSM6K405TU #	\$ 20	+/-10	2	-	307	214	164	126	-	-	3.4	195	
	SSM6K404TU #	\$ 20	+/-10	3	-	147	100	70	55	-	-	5.9	400	
	SSM6K403TU #	\$ 20	+/-10	4.2	-	66	43	32	28	-	-	16.8	1050	
	SSM6K406TU #	\$ 30	+/-20	4.4	-	-	-	-	-	38.5	25	12.4	490	
	SSM6K407TU #	\$ 60	+/-20	2	-	-	-	-	440	-	300	6	150	

★ Under Development (The specification is subject to change without notice.)

AEC-Q101 qualified, \$ With protection Zener diode between gate and source





SOT-23F	TSOP6F	UDFN6B (SOT-1220)
		
2.9 x 2.4	2.9 x 2.8	2.0 x 2.0

Bottom View

N-Channel Single MOSFET

Package	Part Number	V _{BS} (V)	V _{ES} (V)	I _D (A)	R _{DS(ON)} max (mΩ)							Q _g typ. (nC)	C _{iss} typ. (pF)	Note	
					V _{ES} =1.2 V	V _{GS} =1.5 V	V _{GS} =1.8 V	V _{GS} =2.5 V	V _{GS} =4 V	V _{GS} =4.5 V	V _{GS} =10 V				
UDFN6B	SSM6K518NU	\$	20	+/-8	6	-	108	74	45	-	33	-	3.6	410	
	SSM6K517NU	\$	30	+12/-8	6	-	-	82	53	-	39.1	-	3.2	310	
	SSM6K504NU	# \$	30	+/-20	9	-	-	-	-	-	26	19.5	4.8	620	
	SSM6K513NU		30	+/-20	15	-	-	-	-	-	12	8.9	7.5	1130	
	SSM6K516NU	\$	30	+20/-12	6	-	-	-	-	-	64	46	2.5	280	
	SSM6K514NU	40	+/-20	12	-	-	-	-	-	17.3	11.6	7.5	1110		
	SSM6K388NU★	60	+/-20	2	-	-	-	-	-	98	82	TBD	TBD		
	SSM6K389NU★	60	+/-20	2	-	-	-	-	-	200	155	TBD	TBD		
	SSM6K341NU	\$	60	+/-20	6	-	-	-	-	69	51	36	9.3	550	
	SSM6K387NU★	100	+/-20	2	-	-	-	-	-	200	125	TBD	TBD		
SOT-23F	SSM6K361NU	\$	100	+/-20	3.5	-	-	-	-	92	69	3.2	430		
	SSM3K344R	\$	20	+/-8	3	-	232	139	91	-	71	-	2	153	
	SSM3K345R	\$	20	+/-8	4	-	108	74	45	-	33	-	3.6	410	
	SSM3K324R	\$	30	+/-12	4	-	-	109	72	-	56	-	2.2	200	
	SSM3K376R	# \$	30	+12/-8	4	-	-	109	72	-	56	-	2.2	200	
	SSM3K336R	# \$	30	+/-20	3	-	-	-	-	-	140	95	1.7	126	
	SSM3K333R	#	30	+/-20	6	-	-	-	-	-	42	28	3.4	436	
	SSM3K335R	# \$	30	+/-20	6	-	-	-	-	-	56	38	2.7	340	
	SSM3K347R	# \$	38	+/-20	2	-	-	-	-	480	410	340	2.5	86	Built-in Active Clamp Zener
	SSM3K337R	# \$	38	+/-20	2	-	-	-	-	200	176	150	3	120	Built-in Active Clamp Zener
TSOP6F	SSM3K339R	\$	40	+/-12	2	-	-	390	238	208 (@3.6V) 201 (@4.2V)	198	185 (@8V)	1.1	130	
	SSM3K357R	# \$	60	+/-12	0.65	-	-	-	2400 (@3V)	-	1800 (@5V)	-	1.5	43	Built-in Gate-Drain Zener
	SSM3K2615R	# \$	60	+/-20	2	-	-	-	580 (@3.3V)	440	-	300	6	150	
	SSM3K388R★	60	+/-20	2	-	-	-	-	-	98	82	TBD	TBD		
	SSM3K389R★	60	+/-20	2	-	-	-	-	-	200	155	TBD	TBD		
	SSM3K318R	# \$	60	+/-20	2.5	-	-	-	-	-	145	107	7	235	
	SSM3K341R	# \$	60	+/-20	6	-	-	-	-	69	51	36	9.3	550	T _{ch} = 175 °C
	SSM3K387R★	100	+/-20	2	-	-	-	-	-	200	125	TBD	TBD		
	SSM3K361R	# \$	100	+/-20	3.5	-	-	-	-	92	69	3.2	430	T _{ch} = 175 °C	
	SSM6K824R	☆ \$	20	+/-8	6	-	108	74	45	-	33	-	3.6	410	
TSOP6F	SSM6K818R	☆ #	30	+/-20	15	-	-	-	-	-	12	8.9	7.5	1130	
	SSM6K804R	☆ #	40	+/-20	12	-	-	-	-	-	18	12	7.5	1110	
	SSM6K388R★	60	+/-20	2	-	-	-	-	-	98	82	TBD	TBD		
	SSM6K389R★	60	+/-20	2	-	-	-	-	-	200	155	TBD	TBD		
	SSM6K809R	# \$	60	+/-20	6	-	-	-	-	69	51	36	9.3	550	T _{ch} = 175 °C
	SSM6K387R★	100	+/-20	2	-	-	-	-	-	200	125	TBD	TBD		
	SSM6K810R	# \$	100	+/-20	3.5	-	-	-	-	92	69	3.2	430	T _{ch} = 175 °C	
	SSM6K819R	# \$	100	+/-20	10	-	-	-	-	-	36.4	25.8	8.5	1110	T _{ch} = 175 °C

☆ New Products, ★ Under Development (The specification is subject to change without notice.)
AEC-Q101 qualified, \$ With protection Zener diode between gate and source

ES6 (SOT-563)	UF6 (SOT-363F)	UDFN6 (SOT-1118)	DFN2020(WF)
			
1.6 x 1.6	2.0 x 2.1	2.0 x 2.0	2.0 x 2.0

Dual MOSFET

Package	Polarity	Part Number	V _{oss} (V)	V _{ess} (V)	I _D (A)	R _{DS(ON)} max (mΩ)						Q _g typ. (nC)	C _{iss} typ. (pF)	Note		
						V _{GS} = 1.2 V	V _{GS} = 1.5 V	V _{GS} = 1.8 V	V _{GS} = 2.5 V	V _{GS} = 4 V	V _{GS} = 4.5 V				V _{GS} = 10 V	
ES6	P-ch x2	SSM6P41FE	\$	-20	+/-8	-0.72	-	1040	670	440	-	300	-	1.76	110	
		SSM6P56FE	\$	-20	+/-8	-0.8	4000	900	660	480	-	390	-	1.6	100	
		SSM6P76FE ★	\$	-20	+/-8	-0.8	4000	900	660	480	-	390	-	1.6	100	Low leakage current
	N-ch x2	SSM6N36FE #	\$	20	+/-10	0.5	-	1520	1140	850	-	660	630 (@5 V)	1.23	46	
		SSM6N56FE	\$	20	+/-8	0.8	-	840	480	300	-	235	-	1	55	
		SSM6N76FE ★	\$	20	+/-8	0.8	-	840	480	300	-	235	-	1	55	Low leakage current
	N-ch + P-ch	SSM6L14FE	\$	20	+/-10	0.8	-	600	450	330	-	240	-	2	90	
		SSM6L56FE	\$	-20	+/-8	-0.72	-	1040	670	440	-	300	-	1.76	110	
			SSM6L56FE	\$	20	+/-8	0.8	-	840	480	300	-	235	-	1	55
		SSM6L56FE	\$	-20	+/-8	-0.8	4000	900	660	480	-	390	-	1.6	100	
UDFN6	P-ch x2	SSM6P47NU	\$	-20	+/-8	-4	-	242	170	125	-	95	-	4.6	290	
		SSM6P69NU #	\$	-20	+6/-12	-4	-	-	157	76	-	56	45	6.74	480	
		SSM6P49NU	\$	-20	+/-12	-4	-	-	157	76	-	56	45	6.74	480	
	N-ch x2	SSM6N61NU #	\$	20	+/-8	4	-	108	74	45	-	33	-	3.6	410	
		SSM6N55NU	\$	30	+/-20	4	-	-	-	-	-	64	46	2.5	280	
		SSM6N67NU #	\$	30	+12/-8	4	-	-	82	53	-	39.1	-	3.2	310	
		SSM6N68NU #	\$	30	+12/-8	4	-	-	180	117	-	84	-	1.8	129	
		SSM6N57NU	\$	30	+/-12	4	-	-	82	53	-	39.1	-	3.2	310	
		SSM6N58NU	\$	30	+/-12	4	-	-	180	117	-	84	-	1.8	129	
	N-ch + P-ch	SSM6L61NU	\$	20	+/-8	4	-	108	74	45	-	33	-	3.6	410	
SSM6L61NU		\$	-20	+/-12	-4	-	-	157	76	-	56	45	6.74	480		
DFN2020 (WF)	N-ch x2	XSM6N65NW ★ #	\$	30	+20/-12	4	-	-	-	-	64	-	2.5	280	Automotive equipment	
		XSM6N67NW ★ #	\$	30	+12/-8	4	-	-	82	53	-	39.1	-	3.2	310	
UF6	P-ch x2	SSM6P39TU #	\$	-20	+/-8	-1.5	-	-	430	294	213	-	-	6.4	250	
		SSM6P40TU #	\$	-30	+/-20	-1.4	-	-	-	-	403	-	226	2.9	120	
	N-ch x2	SSM6N36TU #	\$	20	+/-10	0.5	-	1520	1140	850	-	660	630 (@5 V)	1.23	46	
		SSM6N62TU #	\$	20	+/-8	0.8	456	173	120	98	-	85	-	2	177	
		SSM6N39TU #	\$	20	+/-10	1.6	-	247	190	139	119	-	-	7.5	260	
		SSM6N24TU #	\$	30	+/-12	0.5	-	-	-	180	-	145	-	-	245	
		SSM6N40TU #	\$	30	+/-20	1.6	-	-	-	-	182	-	122	5.1	180	
	N-ch + P-ch	SSM6L39TU #	\$	20	+/-10	1.6	-	247	190	139	119	-	-	7.5	260	
			\$	-20	+/-8	-1.5	-	-	430	294	213	-	-	6.4	250	
		SSM6L12TU #	\$	30	+/-12	0.5	-	-	-	180	-	145	-	-	245	
\$			-20	+/-12	-0.5	-	-	-	430	260	-	-	-	218		
SSM6L40TU #	\$	30	+/-20	1.6	-	-	-	-	182	-	122	5.1	180			
		SSM6L40TU #	\$	-30	+/-20	-1.4	-	-	-	-	403	-	226	2.9	120	

★ Under Development (The specification is subject to change without notice.)
AEC-Q101 qualified, \$ With protection Zener diode between gate and source

US6 (SOT-363)	TSOP6F	TCSP6A- 172101	TCSPAC- 153001	TCSPED- 302701	TCSPAG- 341501
					
Bottom View	Bottom View	Bottom View	Bottom View	Bottom View	Bottom View
2.0 x 2.1	2.9 x 2.8	2.14 x 1.67	2.98 x 1.49	3.0 x 2.74	3.37 x 1.47

Dual MOSFET

Package	Polarity	Part Number	V _{bss} or V _{SSS} (V)	V _{GSS} (V)	I _D or I _L (A)	R _{DS(ON)} max or R _{SS(ON)} max (mΩ)							Q _g typ. (nC)	C _{iss} typ. (pF)	Note
						V _{Gs} = 1.2 V	V _{Gs} = 1.5 V	V _{Gs} = 1.8 V	V _{Gs} = 2.5 V	V _{Gs} = 4 V	V _{Gs} = 4.5 V	V _{Gs} = 10 V			
US6	N-ch x 2	SSM6N43FU # \$	20	+/-10	0.5	-	1520	1140	850	-	660	630 (@5 V)	1.23	46	
TSOP6F	N-ch x 2	SSM6N357R # \$	60	+/-12	0.65	-	-	-	2400 (@3 V)	-	1800 (@5 V)	-	1.5	43	Built-in Gate-Drain Zener
		SSM6N815R \$	100	+/-20	2	-	-	-	-	180	142	103	3.1	290	
		SSM6N813R # \$	100	+/-20	3.5	-	-	-	-	-	154	112	3.6	242	T _{ch} = 175 °C
	P-ch x 2	SSM6P816R \$	-20	+/-10	-6	-	-	52.3	38.8	-	30.1	-	16.6	1030	
			30	+/-12	4	-	-	82	53	-	39.1	-	3.2	310	
			-20	+/-12	-4	-	-	157	76	-	56	45	6.74	480	
N-ch + P-ch	SSM6L820R # \$	30	+12/-8	4	-	-	82	53	-	39.1	-	3.2	310		
		-20	+6/-12	-4	-	-	157	76	-	56	45	6.7	480		
TCSP6A- 172101	N-ch x 2	SSM6N951L \$	12	+/-8	8	-	-	-	10	5.5 (@3.8 V)	5.1	-	26	-	Drain common
TCSPAC- 153001	N-ch x 2	SSM10N954L \$	12	+/-8	13.5	-	-	-	6.1	2.85 (@3.8 V)	2.75	-	25	-	Drain common
TCSPED- 302701	N-ch x 2	SSM14N956L ☆ \$	12	+/-8	20	-	-	-	3.2	1.5 (@3.8 V)	1.35	-	76	-	Drain common
TCSPAG- 341501	N-ch x 2	SSM10N961L ☆ \$	30	+/-20	14	-	-	-	-	-	17.6	12.8	8.8	-	Drain common

☆ New Products

AEC-Q101 qualified, \$ With protection Zener diode between gate and source

■ Less than 500mA Series MOSFETs (Standard Type)

Package Dimensions (unit: mm)

CST3C	CST3 (SOT-883)	VESM (SOT-723)	SSM (SOT-416)	UFM (SOT-323F)	USM (SOT-323)	S-Mini (SOT-346)
Bottom View						
	0.8 x 0.6	1.0 x 0.6	1.2 x 1.2	1.6 x 1.6	2.0 x 2.1	2.0 x 2.1

P-Channel Single MOSFET

Package	Part Number	V _{oss} (V)	V _{ess} (V)	I _D (A)	R _{DS(ON)} max (Ω)						Note		
					V _{GS} = -1.2 V	V _{GS} = -1.5 V	V _{GS} = -1.8 V	V _{GS} = -2.5 V	V _{GS} = -4 V	V _{GS} = -4.5 V		V _{GS} = -10 V	
CST3C	SSM3J35CTC	\$	-20	+/-10	-0.25	20	4	2.9	2.1	-	1.4	-	
	SSM3J78CTC ★	\$	-20	+/-10	-0.25	20	4	2.9	2.1	-	1.4	-	Low leakage current
CST3	SSM3J35CT	\$	-20	+/-10	-0.1	44	22	-	11	8	-	-	
	SSM3J16CT ●	\$	-20	+/-10	-0.1	-	45	-	12	8	-	-	⇒ SSM3J35CT
	SSM3J15CT	\$	-30	+/-20	-0.1	-	-	-	32	12	-	-	
VESM	SSM3J35MFV #	\$	-20	+/-10	-0.1	44	22	-	11	8	-	-	⇒ SSM3J35AMFV (General purpose) ⇒ SSM3J35MFV,LXGF(T) (Automotive equipment)
	SSM3J36MFV #	\$	-20	+/-8	-0.33	-	3.6	2.7	1.6 (@-2.8V)	-	1.31	-	⇒ SSM3J56MFV (General purpose) ⇒ SSM3J36MFV,LXGF(T) (Automotive equipment)
	SSM3J35AMFV	\$	-20	+/-10	-0.25	20	4	2.9	2.1	-	1.4	-	
	SSM3J78MFV ★	\$	-20	+/-10	-0.25	20	4	2.9	2.1	-	1.4	-	Low leakage current
	SSM3J15FV #	\$	-30	+/-20	-0.1	-	-	-	32	12	-	-	
SSM	SSM3J35FS #	\$	-20	+/-10	-0.1	44	22	-	11	8	-	-	⇒ SSM3J35AFS (General purpose) ⇒ SSM3J35FS,LXGF(T) (Automotive equipment)
	SSM3J35AFS	\$	-20	+/-10	-0.25	20	4	2.9	2.1	-	1.4	-	
	SSM3J78FS ★	\$	-20	+/-10	-0.25	20	4	2.9	2.1	-	1.4	-	Low leakage current
	SSM3J36FS #	\$	-20	+/-8	-0.33	-	3.6	2.7	1.6 (@-2.8V)	-	1.31	-	
	SSM3J15FS #	\$	-30	+/-20	-0.1	-	-	-	32	12	-	-	
UFM	SSM3J36TU #	\$	-20	+/-8	-0.33	-	3.6	2.7	1.6 (@-2.8V)	-	1.31	-	
USM	SSM3J15FU #	\$	-30	+/-20	-0.1	-	-	-	32	12	-	-	
S-Mini	SSM3J15F #	\$	-30	+/-20	-0.1	-	-	-	32	12	-	-	
	2SJ305	\$	-30	+/-20	-0.2	-	-	-	4	-	-	-	
	SSM3J168F #	\$	-60	+10/-20	-0.4	-	-	-	-	2	1.9	1.55	

● Recommended Another New Product, ★ Under Development (The specification is subject to change without notice.)

AEC-Q101 qualified, \$ With protection Zener diode between gate and source

CST3C	CST3 (SOT-883)	VESM (SOT-723)	SSM (SOT-416)	USM (SOT-323)	SOT23 (SOT-23)	S-Mini (SOT-346)
Bottom View 	Bottom View 					
0.8 x 0.6	1.0 x 0.6	1.2 x 1.2	1.6 x 1.6	2.0 x 2.1	2.9 x 2.4	2.9 x 2.5

N-Channel Single MOSFET

Package	Part Number	V _{DS} (V)	V _{GS} (V)	I _D (A)	R _{DS(ON)} max (Ω)								Note
					V _{GS} = 1.2V	V _{GS} = 1.5V	V _{GS} = 1.8V	V _{GS} = 2.5V	V _{GS} = 4V	V _{GS} = 4.5V	V _{GS} = 5V	V _{GS} = 10V	
CST3C	SSM3K35CTC	\$ 20	+/-10	0.25	9	3.1	2.4	1.6	-	1.1	-	-	
	SSM3K78CTC ★	\$ 20	+/-10	0.25	9	3.1	2.4	1.6	-	1.1	-	-	Low leakage current
	SSM3K15ACTC	\$ 30	+/-20	0.1	-	-	-	6	3.6	-	-	-	
	SSM3K79CTC ★	\$ 30	+/-20	0.1	-	-	-	6	3.6	-	-	-	Low leakage current
	SSM3K72CTC	\$ 60	+/-20	0.15	-	-	-	5.7 (typ.)	-	4.7	4.4	3.9	
CST3	SSM3K16CT	\$ 20	+/-10	0.1	-	15	-	4	3	-	-	-	
	SSM3K35CT	\$ 20	+/-10	0.18	20	8	-	4	3	-	-	-	
	SSM3K37CT	\$ 20	+/-10	0.2	-	5.6	4.05	3.02	-	2.2	-	-	
	SSM3K77CT ★	\$ 20	+/-10	0.2	-	5.6	4.05	3.1	-	2.2	-	-	Low leakage current
	SSM3K15CT ●	\$ 30	+/-20	0.1	-	-	-	7	4	-	-	-	⇒ SSM3K15ACT
	SSM3K15ACT	\$ 30	+/-20	0.1	-	-	-	6	3.6	-	-	-	
	SSM3K79CT ★	\$ 30	+/-20	0.1	-	-	-	6	3.6	-	-	-	Low leakage current
	SSM3K72KCT	\$ 60	+/-20	0.4	-	-	-	-	-	1.75	1.65	1.5	
	SSM3K16FV	\$ 20	+/-10	0.1	-	15	-	4	3	-	-	-	
VESM	SSM3K35MFV #	\$ 20	+/-10	0.18	20	8	-	4	3	-	-	-	⇒ SSM3K35AMFV (General purpose) ⇒ SSM3K35MFV,LXGF(T) (Automotive equipment)
	SSM3K37MFV	\$ 20	+/-10	0.25	-	5.6	4.05	3.02	-	2.2	-	-	
	SSM3K77MFV ★	\$ 20	+/-10	0.25	-	5.6	4.05	3.1	-	2.2	-	-	Low leakage current
	SSM3K35AMFV	\$ 20	+/-10	0.25	9	3.1	2.4	1.6	-	1.1	-	-	
	SSM3K78MFV ★	\$ 20	+/-10	0.25	9	3.1	2.4	1.6	-	1.1	-	-	Low leakage current
	SSM3K15AMFV	\$ 30	+/-20	0.1	-	-	-	6	3.6	-	-	-	
	SSM3K79MFV ★	\$ 30	+/-20	0.1	-	-	-	6	3.6	-	-	-	Low leakage current
	SSM3K44MFV #	\$ 30	+/-20	0.1	-	-	-	7	4	-	-	-	
SSM	SSM3K16FS	\$ 20	+/-10	0.1	-	15	-	4	3	-	-	-	⇒ SSM3K37FS
	SSM3K35FS #	\$ 20	+/-10	0.18	20	8	-	4	3	-	-	-	⇒ SSM3K35AFS (General purpose) ⇒ SSM3K35FS,LXGF(T) (Automotive equipment)
	SSM3K37FS	\$ 20	+/-10	0.2	-	5.6	4.05	3.02	-	2.2	-	-	
	SSM3K77FS ★	\$ 20	+/-10	0.2	-	5.6	4.05	3.1	-	2.2	-	-	Low leakage current
	SSM3K35AFS	\$ 20	+/-10	0.25	9	3.1	2.4	1.6	-	1.1	-	-	
	SSM3K78FS ★	\$ 20	+/-10	0.25	9	3.1	2.4	1.6	-	1.1	-	-	Low leakage current
	SSM3K15FS ● #	\$ 30	+/-20	0.1	-	-	-	7	4	-	-	-	⇒ SSM3K15AFS (General purpose) ⇒ SSM3K44FS,LXGF(T) (Automotive equipment)
	SSM3K44FS #	\$ 30	+/-20	0.1	-	-	-	7	4	-	-	-	
	SSM3K15AFS	\$ 30	+/-20	0.1	-	-	-	6	3.6	-	-	-	
	SSM3K79FS ★	\$ 30	+/-20	0.1	-	-	-	6	3.6	-	-	-	Low leakage current
	SSM3K72CFs	\$ 60	+/-20	0.17	-	-	-	-	-	4.7	4.4	3.9	
	SSM3K72KFS #	\$ 60	+/-20	0.3	-	-	-	-	-	1.75	1.65	1.5	
	SSM3K16FU	\$ 20	+/-10	0.1	-	15	-	4	3	-	-	-	
USM	SSM3K15FU #	\$ 30	+/-20	0.1	-	-	-	7	4	-	-	-	⇒ SSM3K15AFU (General purpose) ⇒ SSM3K15FU,LXGF(T) (Automotive equipment)
	SSM3K15AFU	\$ 30	+/-20	0.1	-	-	-	6	3.6	-	-	-	
	SSM3K79FU ★	\$ 30	+/-20	0.1	-	-	-	6	3.6	-	-	-	Low leakage current
	SSM3K48FU ●	\$ 30	+/-20	0.1	-	-	-	5.4	3.2	-	-	-	⇒ SSM3K15AFU
	SSM3K09FU	\$ 30	+/-20	0.4	-	-	-	1.7 (@3.3V)	1.2	-	-	0.7	
	SSM3K17FU #	\$ 50	+/-7	0.1	-	-	-	40	20	-	-	-	
	SSM3K7002CFU	\$ 60	+/-20	0.17	-	-	-	-	-	4.7	4.4	3.9	
	SSM3K7002KFU #	\$ 60	+/-20	0.4	-	-	-	-	-	1.75	1.65	1.5	
SOT23	T2N7002AK	\$ 60	+/-20	0.2	-	-	-	-	-	4.7	4.4	3.9	
	T2N7002BK	\$ 60	+/-20	0.4	-	-	-	-	-	1.75	1.65	1.5	
S-Mini	SSM3K15F	\$ 30	+/-20	0.1	-	-	-	7	4	-	-	-	
	2SK2009	\$ 30	+/-20	0.2	-	-	-	2	-	-	-	-	
	SSM3K7002KF	\$ 60	+/-20	0.4	-	-	-	-	-	1.75	1.65	1.5	

● Recommended Another New Product, # AEC-Q101 qualified, \$ With protection Zener diode between gate and source
★ Under Development (The specification is subject to change without notice.)

ESV (SOT-553)	ES6 (SOT-563)	USV (SOT-353)	UF6 (SOT-363F)
			
1.6 x 1.6	1.6 x 1.6	2.0 x 2.1	2.0 x 2.1

Dual MOSFET

Package	Polarity	Part Number	V _{oss} (V)	V _{ess} (V)	I _b (A)	R _{DS(ON)} max (Ω)								Note	
						V _{es} = 1.2 V	V _{es} = 1.5 V	V _{es} = 1.8 V	V _{es} = 2.5 V	V _{es} = 4 V	V _{es} = 4.5 V	V _{es} = 5 V	V _{es} = 10 V		
ESV	P-ch x 2	SSM5P16FE	\$	-20	+/-10	-0.1	-	45	-	12	8	-	-	-	
	N-ch x 2	SSM5N16FE	\$	20	+/-10	0.1	-	15	-	4	3	-	-	-	
		SSM5N15FE	\$	30	+/-20	0.1	-	-	-	7	4	-	-	-	
ES6	P-ch x 2	SSM6P35FE	# \$	-20	+/-10	-0.1	44	22	-	11	8	-	-	-	⇒ SSM6P35AFE (General purpose) ⇒ SSM6P35FE, LXGM(T) (Automotive equipment)
		SSM6P35AFE	\$	-20	+/-10	-0.25	20	4	2.9	2.1	-	1.4	-	-	
		SSM6P78FE	★ \$	-20	+/-10	-0.25	20	4	2.9	2.1	-	1.4	-	-	Low leakage current
		SSM6P36FE	# \$	-20	+/-8	-0.33	-	3.6	2.7	1.6 (@-2.8V)	-	1.31	-	-	
		SSM6P15FE	# \$	-30	+/-20	-0.1	-	-	-	32	12	-	-	-	
	N-ch x 2	SSM6N16FE	\$	20	+/-10	0.1	-	15	-	4	3	-	-	-	
		SSM6N35FE	# \$	20	+/-10	0.18	20	8	-	4	3	-	-	-	⇒ SSM6N35AFE (General purpose) ⇒ SSM6N35FE, LXGM(T) (Automotive equipment)
		SSM6N37FE	\$	20	+/-10	0.25	-	5.6	4.05	3.02	-	2.2	-	-	
		SSM6N77FE	★ \$	20	+/-10	0.25	-	5.6	4.05	3.1	-	2.2	-	-	Low leakage current
		SSM6N35AFE	\$	20	+/-10	0.25	9	3.1	2.4	1.6	-	1.1	-	-	
		SSM6N78FE	★ \$	20	+/-10	0.25	9	3.1	2.4	1.6	-	1.1	-	-	Low leakage current
		SSM6N44FE	# \$	30	+/-20	0.1	-	-	-	7	4	-	-	-	
		SSM6N15AFE	\$	30	+/-20	0.1	-	-	-	6	3.6	-	-	-	
	SSM6N79FE	★ \$	30	+/-20	0.1	-	-	-	6	3.6	-	-	-	Low leakage current	
	SSM6N7002BFE	\$	60	+/-20	0.2	-	-	-	-	-	3.3	2.6	2.1		
N-ch + P-ch	SSM6L35FE	# \$	20	+/-10	0.18	20	8	-	4	3	-	-	-		
		-20	+/-10	-0.1	44	22	-	11	8	-	-	-			
	SSM6L36FE	# \$	20	+/-10	0.5	-	1.52	1.14	0.85	-	0.66	0.63	-		
USV	P-ch x 2	SSM5P15FU	\$	-30	+/-20	-0.1	-	-	-	32	12	-	-	-	
	N-ch x 2	SSM5N16FU	\$	20	+/-10	0.1	-	15	-	4	3	-	-	-	
		SSM5N15FU	\$	30	+/-20	0.1	-	-	-	7	4	-	-	-	
UF6	P-ch x 2	SSM6P36TU	# \$	-20	+/-8	-0.33	-	3.6	2.7	1.6 (@-2.8V)	-	1.31	-	-	
	N-ch + P-ch	SSM6L36TU	# \$	20	+/-10	0.5	-	1.52	1.14	0.85	-	0.66	0.63	-	

AEC-Q101 qualified, \$ With protection Zener diode between gate and source
 ★ Under Development (The specification is subject to change without notice.)

US6
(SOT-363)



2.0 x 2.1




Dual MOSFET

Package	Polarity	Part Number	V _{boss} (V)	V _{ess} (V)	I _b (A)	R _{DS(on)} max (Ω)								Note
						V _{GS} = 1.2 V	V _{GS} = 1.5 V	V _{GS} = 1.8 V	V _{GS} = 2.5 V	V _{GS} = 4 V	V _{GS} = 4.5 V	V _{GS} = 5 V	V _{GS} = 10 V	
US6	P-ch x 2	SSM6P35FU # \$	-20	+/-10	-0.1	44	22	-	11	8	-	-	-	⇒ SSM6P35AFU (General purpose) ⇒ SSM6P35FU, LXGF(T) (Automotive equipment)
		SSM6P35AFU \$	-20	+/-10	-0.25	20	4	2.9	2.1	-	1.4	-	-	
		SSM6P78FU ★ \$	-20	+/-10	-0.25	20	4	2.9	2.1	-	1.4	-	-	Low leakage current
		SSM6P15FU # \$	-30	+/-20	-0.1	-	-	-	32	12	-	-	-	
	N-ch x 2	SSM6N16FU \$	20	+/-10	0.1	-	15	-	4	3	-	-	-	
		SSM6N35FU # \$	20	+/-10	0.18	20	8	-	4	3	-	-	-	⇒ SSM6N35AFU (General purpose) ⇒ SSM6N35FU, LXGF(T) (Automotive equipment)
		SSM6N35AFU \$	20	+/-10	0.25	9	3.1	2.4	1.6	-	1.1	-	-	
		SSM6N78FU ★ \$	20	+/-10	0.25	9	3.1	2.4	1.6	-	1.1	-	-	Low leakage current
		SSM6N37FU \$	20	+/-10	0.25	-	5.6	4.05	3.02	-	2.2	-	-	
		SSM6N77FU ★ \$	20	+/-10	0.25	-	5.6	4.05	3.1	-	2.2	-	-	Low leakage current
		SSM6N48FU ● \$	30	+/-20	0.1	-	-	-	5.4	3.2	-	-	-	⇒ SSM6N15AFU
		SSM6N44FU # \$	30	+/-20	0.1	-	-	-	7	4	-	-	-	
		SSM6N15FU ● \$	30	+/-20	0.1	-	-	-	7	4	-	-	-	⇒ SSM6N15AFU
		SSM6N15AFU \$	30	+/-20	0.1	-	-	-	6	3.6	-	-	-	
		SSM6N79FU ★ \$	30	+/-20	0.1	-	-	-	6	3.6	-	-	-	Low leakage current
		SSM6N09FU \$	30	+/-20	0.4	-	-	-	1.7 (@3.3V)	1.2	-	-	0.7	
		SSM6N17FU # \$	50	+/-7	0.1	-	-	-	40	20	-	-	-	
		SSM6N7002CFU \$	60	+/-20	0.17	-	-	-	-	-	4.7	4.4	3.9	
		SSM6N7002KFU # \$	60	+/-20	0.3	-	-	-	-	-	1.75	1.65	1.5	
		N-ch + P-ch	SSM6L35FU # \$	20	+/-10	0.18	20	8	-	4	3	-	-	-
SSM6L09FU ● \$	30		+/-20	0.4	-	-	-	1.7 (@3.3V)	1.2	-	-	0.7	⇒ SSM6L40TU	
		-30	+/-20	-0.2	-	-	-	6 (@-3.3V)	4.2	-	-	2.7		

● Recommended Another New Product, # AEC-Q101 qualified, \$ With protection Zener diode between gate and source
★ Under Development (The specification is subject to change without notice.)

MOSFET with Diode

Package Dimensions (unit: mm)


ESV (SOT-553)	UFV (SOT-353F)	UDFN6 (SOT-1118)
		Bottom View 
1.6 x 1.6	2.0 x 2.1	2.0 x 2.0

Package	Polarity	Part Number	V _{oss} (V)	V _{gss} (V)	I _D (A)	MOSFET								Diode				Note	
						R _{DS(ON)} max (mΩ)								C _{iss} typ. (pF)	V _R (V)	I _O (A)	V _F max (V)		
						V _{GS} = 1.5V	V _{GS} = 1.8V	V _{GS} = 2.5V	V _{GS} = 4V	V _{GS} = 4.5V	V _{GS} = 5V	V _{GS} = 10V	@I _F (A)						
ESV	P-ch + SBD	SSM5G06FE	\$ -20	+/-10	-0.1	45000	-	12000	8000	-	-	-	11	12	0.1	0.5	0.1		
	N-ch + SBD	SSM5H06FE	\$ 20	+/-10	0.1	15000	-	4000	3000	-	-	-	9.3	12	0.1	0.5	0.1		
UFV	P-ch + SBD	SSM5G02TU	\$ -12	+/-12	-1	-	-	240	160	-	-	-	310	12	0.5	0.43	0.5		
		SSM5G09TU	\$ -12	+/-8	-1.5	-	-	200	130	-	-	-	550	12	0.5	0.43	0.5		
	N-ch + SBD	SSM5G11TU	\$ -30	+/-20	-1.4	-	-	-	403	-	-	226	120	30(¥)	0.7(¥¥)	0.44	0.7(¥¥)		
		N-ch + Switching Diode	SSM5H90ATU	\$ 20	+/-10	2.4	-	-	89	65	-	-	-	200	80	0.1	1.2	0.1	
UDFN6	P-ch + SBD	SSM6G18NU	\$ -20	+/-8	-2	261	185	143	-	112	-	-	270	30	1	0.58	1		
	N-ch + SBD	SSM6H19NU	\$ 40	+/-12	2	-	390	238	208 (@3.5V) 201 (@4.2V)	198	-	185 (@8V)	130	40	0.5	0.57	0.5		

\$ With protection Zener diode between gate and source, ¥ V_{RRM}, ¥¥ I_{F(AV)}

Bipolar Transistor with Diode

Package Dimensions (unit: mm)

SM6 (SOT-26)

2.9 x 2.8

Package	Polarity	Part Number	V _{CEO} (V)	I _C (A)	PNP transistor			Switching Diode				Note
					h _{FE}	V _{CE(sat)} max (V) I _C =-10 mA, I _B =-1 mA	C _{ob} typ. (pF)	V _R (V)	I _O (A)	V _F max (V)		
										V _{CE} =-6 V, I _C =-2 mA	@I _F (A)	
SM6	PNP + Switching Diode	HN2E04F	-120	-0.1	200 to 700	-0.3	4	80	0.1	1.2	0.1	

■ Part Naming Conventions

Small-Signal MOSFET SSM / XSM Series




Ex.) SSM 3 K 329 — R
 ① ② ③ ④ ⑤ ⑥

- | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
|--|---|--------|---|-------|--------|--|---------|--|---------|--|---------|--|---------|--|----------|--|---------|--|---------|-------|-----------|--|----------|--|--------------------------------|--|------------|--|-----------|--|------------|--|---------|--|------------|--|---------|--|--|--|---------|--|--|--|--------------------|--|--|--|-----------------|--|--|--------|---|--|--|--------|--------------------------------|
| <p>① Small-Signal MOSFET
 SSM : Initial of "Small-Signal MOSFET"
 XSM : Initial of "Automotive Small-Signal MOSFET"</p> <p>② Pin count</p> <p>③ Polarity and internal configuration
 K : N-channel, single
 J : P-channel, single
 N : N-channel, dual
 P : P-channel, dual
 L : N-channel and P-channel (dual)
 E : N-channel and P-channel (pre-wired as a load switch)
 H : N-channel and SBD (or Switching diode)
 G : P-channel and SBD</p> | <p>④ Serial number of the products</p> <p>⑤ There may be a symbol that indicates chip change etc.</p> <p>⑥ Package</p> <table border="0"> <tr> <td>3-pin</td> <td>F: S-Mini</td> <td>5-pin</td> <td>F: SMV</td> </tr> <tr> <td></td> <td>FU: USM</td> <td></td> <td>FU: USV</td> </tr> <tr> <td></td> <td>FS: SSM</td> <td></td> <td>FE: ESV</td> </tr> <tr> <td></td> <td>FV: VESM</td> <td></td> <td>TU: UFV</td> </tr> <tr> <td></td> <td>TU: UFM</td> <td>6-pin</td> <td>G: WCSP6C</td> </tr> <tr> <td></td> <td>CT: CST3</td> <td></td> <td>L: Chip LGA
(TCSP6A-172101)</td> </tr> <tr> <td></td> <td>CTB: CST3B</td> <td></td> <td>R: TSOP6F</td> </tr> <tr> <td></td> <td>CTC: CST3C</td> <td></td> <td>FU: US6</td> </tr> <tr> <td></td> <td>R: SOT-23F</td> <td></td> <td>FE: ES6</td> </tr> <tr> <td></td> <td></td> <td></td> <td>TU: UF6</td> </tr> <tr> <td></td> <td></td> <td></td> <td>NU: UDFN6 / UDFN6B</td> </tr> <tr> <td></td> <td></td> <td></td> <td>NW: DFN2020(WF)</td> </tr> <tr> <td></td> <td></td> <td>10-pin</td> <td>L: Chip LGA
(TCSPAC-153001)
(TCSPAG-341501)</td> </tr> <tr> <td></td> <td></td> <td>14-pin</td> <td>L: Chip LGA
(TCSPED-302701)</td> </tr> </table> | 3-pin | F: S-Mini | 5-pin | F: SMV | | FU: USM | | FU: USV | | FS: SSM | | FE: ESV | | FV: VESM | | TU: UFV | | TU: UFM | 6-pin | G: WCSP6C | | CT: CST3 | | L: Chip LGA
(TCSP6A-172101) | | CTB: CST3B | | R: TSOP6F | | CTC: CST3C | | FU: US6 | | R: SOT-23F | | FE: ES6 | | | | TU: UF6 | | | | NU: UDFN6 / UDFN6B | | | | NW: DFN2020(WF) | | | 10-pin | L: Chip LGA
(TCSPAC-153001)
(TCSPAG-341501) | | | 14-pin | L: Chip LGA
(TCSPED-302701) |
| 3-pin | F: S-Mini | 5-pin | F: SMV | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | FU: USM | | FU: USV | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | FS: SSM | | FE: ESV | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | FV: VESM | | TU: UFV | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | TU: UFM | 6-pin | G: WCSP6C | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | CT: CST3 | | L: Chip LGA
(TCSP6A-172101) | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | CTB: CST3B | | R: TSOP6F | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | CTC: CST3C | | FU: US6 | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | R: SOT-23F | | FE: ES6 | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | | | TU: UF6 | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | | | NU: UDFN6 / UDFN6B | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | | | NW: DFN2020(WF) | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | | 10-pin | L: Chip LGA
(TCSPAC-153001)
(TCSPAG-341501) | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | | 14-pin | L: Chip LGA
(TCSPED-302701) | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |

2. Bipolar Transistors















■ General-Purpose Transistors



















Package Dimensions (unit: mm)

Classification	$ V_{CE0} $ (V)	$ I_C $ (mA)	CST3 (SOT-883)		VESM (SOT-723)		SSM (SOT-416)	
			Bottom View					
			 1.0 x 0.6		 1.2 x 1.2		 1.6 x 1.6	
Part Number								
			NPN	PNP	NPN	PNP	NPN	PNP
General Purpose	50	100	2SC6026CT	2SA2154CT				
	50	150			2SC6026MFV #	2SA2154MFV #	2SC4738 #	2SA1832 #

Classification	$ V_{CE0} $ (V)	$ I_C $ (mA)	USM (SOT-232)		UFM (SOT-323F)		S-Mini (SOT-346)		SOT23 (SOT-23)		SOT-23F			
			Part Number											
			NPN	PNP	NPN	PNP	NPN	PNP	NPN	PNP	NPN	PNP	NPN	PNP
General Purpose	30	500		2SA1588 #					2SA1182 #					
	50	150	2SC4116 #	2SA1586 #				2SC2712 #	2SA1162 #	TBC847	TBC857			
		200	TTC4116FU	TTA1586FU							TMBT3904	TMBT3906		
	50	500					2SC3325 #	2SA1313 #						
	45						TTC1949		TTA1713					
Low Noise	120	100	2SC4117 #	2SA1587 #			2SC2713 #	2SA1163 #						
Low Saturation	15	800						2SA1362 #						
Muting	20	300	2SC4213				2SC3326 #							
High Current	20	2500				2SA2215 #						TTA502 # ☆		
	25	800					2SC3265 #	2SA1298 #						
	50	1000			2SC6135 #						TTC500 # ☆	TTA500 # ☆		
	50	1700				2SA2195 #								
	50	2000										TTA501 # ☆		
	50	2500			2SC6100 #							TTC501 # ☆		
High Breakdown	300	100							2SA1721			TTC502 # ☆		

☆ New Products
AEC-Q101 qualified

Classification	$ V_{CE0} $ (V)	$ I_c $ (mA)	ESV (SOT-553)	USV (SOT-353)	SMV (SOT-25)			
			 1.6 x 1.6	 2.0 x 2.1	 2.9 x 2.8			
			Part Number					
			Complementary	NPN x 2	PNP x 2	NPN x 2	PNP x 2	Complementary
General Purpose	50	150	 HN4B01JE	 2SC4944	 2SA1873	 2SC4207	 2SA1618	
					 HN4A56JU			
Low Noise	120	100			 HN4C06J	 HN4A06J	 HN4B06J	
					 HN4C51J	 HN4A51J		


Classification	$ V_{CE0} $ (V)	$ I_c $ (mA)	ES6 (SOT-563)			US6 (SOT-363)			SM6 (SOT-26)		
			 1.6 x 1.6			 2.0 x 2.1			 2.9 x 2.8		
			Part Number								
			NPN x 2	PNP x 2	Complementary	NPN x 2	PNP x 2	Complementary	NPN x 2	PNP x 2	Complementary
General Purpose	50	150	 HN1C01FE #	 HN1A01FE #		 HN1C01FU #	 HN1A01FU #	 HN1B01FU #	 HN1C01F	 HN1A01F	 HN1B01F
					 HN1B04FE #		 HN1B04FU #				
	50	500							 HN1C07F	 HN1A07F	
High Current	15	800								 HN1A02F	
Muting	20	300				 HN1C03FU #			 HN1C03F		


AEC-Q101 qualified

Bias Resistor Built-in Transistors (BRTs)

Package Dimensions (unit: mm)

V _{ce(s)} (V)	I _c (mA)	Resistance		VESM (SOT-723)	SSM (SOT-416)	USM (SOT-323)	S-Mini (SOT-346)				
		1.2 x 1.2		1.6 x 1.6		2.0 x 2.1		2.9 x 2.5			
		R1 typ. (kΩ)	R2 typ. (kΩ)	NPN	PNP	NPN	PNP	NPN	PNP		
Part Number											
50	100	4.7	4.7	RN1101MFV #	RN2101MFV #	RN1101 #	RN2101 #	RN1301 #	RN2301 #	RN1401 #	RN2401 #
		10	10	RN1102MFV #	RN2102MFV #	RN1102 #	RN2102 #	RN1302 #	RN2302 #	RN1402 #	RN2402 #
		22	22	RN1103MFV #	RN2103MFV #	RN1103 #	RN2103 #	RN1303 #	RN2303 #	RN1403 #	RN2403 #
		47	47	RN1104MFV #	RN2104MFV #	RN1104 #	RN2104 #	RN1304 #	RN2304 #	RN1404 #	RN2404 #
		2.2	47	RN1105MFV #	RN2105MFV #	RN1105 #	RN2105 #	RN1305 #	RN2305 #	RN1405 #	RN2405 #
		4.7	47	RN1106MFV #	RN2106MFV #	RN1106 #	RN2106 #	RN1306 #	RN2306 #	RN1406 #	RN2406 #
		10	47	RN1107MFV #	RN2107MFV #	RN1107 #	RN2107 #	RN1307 #	RN2307 #	RN1407 #	RN2407 #
		22	47	RN1108MFV #	RN2108MFV #	RN1108 #	RN2108 #	RN1308 #	RN2308 #	RN1408 #	RN2408 #
		47	22	RN1109MFV #	RN2109MFV #	RN1109 #	RN2109 #	RN1309 #	RN2309 #	RN1409 #	RN2409 #
		4.7	-	RN1110MFV #	RN2110MFV #	RN1110 #	RN2110 #	RN1310 #	RN2310 #	RN1410 #	RN2410 #
		10	-	RN1111MFV #	RN2111MFV #	RN1111 #	RN2111 #	RN1311 #	RN2311 #	RN1411 #	RN2411 #
		22	-	RN1112MFV #	RN2112MFV #	RN1112 #	RN2112 #	RN1312 #	RN2312	RN1412 #	RN2412 #
		47	-	RN1113MFV #	RN2113MFV #	RN1113 #	RN2113 #	RN1313 #	RN2313	RN1413 #	RN2413 #
		1	10	RN1114MFV #	RN2114MFV #	RN1114 #	RN2114	RN1314 #	-	RN1414 #	RN2414 #
		2.2	10	RN1115MFV #	RN2115MFV #	RN1115 #	RN2115 #	RN1315 #	RN2315	RN1415 #	RN2415 #
		4.7	10	RN1116MFV #	RN2116MFV #	RN1116 #	RN2116 #	RN1316 #	RN2316 #	RN1416 #	RN2416 #
		10	4.7	RN1117MFV #	RN2117MFV #	RN1117	RN2117	RN1317	RN2317	RN1417 #	RN2417 #
		47	10	RN1118MFV #	-	RN1118	-	RN1318	RN2318	RN1418 #	RN2418 #
		1	-	RN1119MFV #	RN2119MFV #	-	-	-	-	-	-
		100	100	RN1130MFV #	RN2130MFV #	-	-	-	-	-	-
100	-	RN1131MFV #	RN2131MFV #	-	-	-	-	-	-		
200	-	RN1132MFV #	RN2132MFV #	-	-	-	-	-	-		

V _{ce(s)} (V)	I _c (mA)	Resistance		SOT23 (SOT-23)	
		2.9 x 2.4			
		R1 typ. (kΩ)	R2 typ. (kΩ)	NPN	PNP
Part Number					
50	100	4.7	4.7	TDTC143E	TDTA143E
		10	10	TDTC144E	TDTA144E
		22	22	TDTC124E	TDTA124E
		47	47	TDTC144E	TDTA144E
		2.2	47	TDTC123J	TDTA123J
		4.7	47	TDTC143Z	TDTA143Z
		10	47	TDTC114Y	TDTA114Y

V _{ce(s)} (V)	I _c (mA)	Resistance		S-Mini (SOT-346)	
		2.9 x 2.5			
		R1 typ. (kΩ)	R2 typ. (kΩ)	NPN	PNP
Part Number					
50	800	1	1	RN1421	RN2421
		2.2	2.2	RN1422	RN2422
		4.7	4.7	RN1423	RN2423
		10	10	RN1424	RN2424
		0.47	10	RN1425	RN2425
		1	10	RN1426	RN2426
		2.2	10	RN1427	RN2427

#AEC-Q101 qualified

1 MOSFETS

2 Tr./BRTs

3 Diodes

4 Power Management ICs

5 Linear ICs






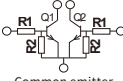
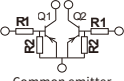
6 Sensors


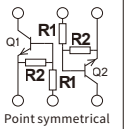
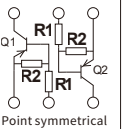
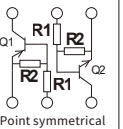
7 General Purpose Logic ICs

8 RF Devices


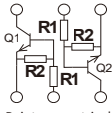

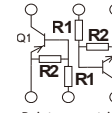
9 Packages


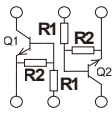
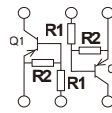
Package Dimensions (unit: mm)

V _{ce0} (V)	I _c (mA)			ESV (SOT-553)		USV (SOT-353)		SMV (SOT-25)			
		Resistance		 1.6 x 1.6		 2.0 x 2.1		 2.9 x 2.8			
				 Common emitter		 Common emitter		 Common emitter		 Common emitter	
		R1 typ. (kΩ)	R2 typ. (kΩ)	NPN x 2		PNP x 2		NPN x 2		PNP x 2	
				Part Number							
50	100	4.7	4.7	RN1701JE	RN2701JE	RN1701 #	RN2701 #	RN1501	RN2501		
		10	10	RN1702JE	RN2702JE	RN1702 #	RN2702 #	RN1502	RN2502		
		22	22	RN1703JE	RN2703JE	RN1703 #	RN2703 #	RN1503	RN2503		
		47	47	RN1704JE	RN2704JE	RN1704 #	RN2704 #	RN1504	RN2504		
		2.2	47	RN1705JE	RN2705JE	RN1705 #	RN2705 #	RN1505	RN2505		
		4.7	47	RN1706JE	RN2706JE	RN1706 #	RN2706 #	RN1506	RN2506		
		10	47	RN1707JE	RN2707JE	RN1707 #	RN2707 #	RN1507	RN2507		
		22	47	RN1708JE	RN2708JE	RN1708 #	RN2708 #	RN1508	-		
		47	22	RN1709JE	RN2709JE	RN1709 #	RN2709 #	RN1509	-		
		4.7	-	RN1710JE	RN2710JE	RN1710 #	RN2710 #	RN1510	RN2510		
		10	-	RN1711JE	RN2711JE	RN1711 #	RN2711 #	RN1511	RN2511		
		22	-	-	RN2712JE	-	-	-	-		
47	-	-	RN2713JE	-	-	-	-				

V _{ce0} (V)	I _c (mA)			ES6 (SOT-563)							
		Resistance		 1.6 x 1.6							
				 Point symmetrical		 Point symmetrical		 Point symmetrical			
		R1 typ. (kΩ)	R2 typ. (kΩ)	NPN x 2		PNP x 2		PNP + NPN			
				Part Number							
50	100	4.7	4.7	RN1901FE #	RN2901FE #	RN4901FE #	RN4981FE #				
		10	10	RN1902FE #	RN2902FE #	RN4902FE #	RN4982FE #				
		22	22	RN1903FE #	RN2903FE #	RN4903FE #	RN4983FE #				
		47	47	RN1904FE #	RN2904FE #	RN4904FE #	RN4984FE #				
		2.2	47	RN1905FE #	RN2905FE #	RN4905FE #	RN4985FE #				
		4.7	47	RN1906FE #	RN2906FE #	RN4906FE #	RN4986FE #				
		10	47	RN1907FE #	RN2907FE #	RN4907FE #	RN4987FE #				
		22	47	RN1908FE #	RN2908FE #	RN4908FE #	RN4988FE #				
		47	22	RN1909FE #	RN2909FE #	RN4909FE #	RN4989FE #				
		4.7	-	RN1910FE #	RN2910FE #	RN4910FE #	RN4990FE #				
		10	-	RN1911FE #	RN2911FE #	RN4911FE #	RN4991FE #				

AEC-Q101 qualified

V _{ce(sat)} (V)	I _c (mA)	US6 (SOT-363)					
		Resistance					
		R1 typ. (kΩ)	R2 typ. (kΩ)	Part Number			
50	100	 2.0 x 2.1					
		 Point symmetrical		 Point symmetrical		 Point symmetrical	
				NPN x 2	PNP x 2	PNP + NPN	NPN + PNP
		4.7	4.7	RN1901 #	RN2901 #	RN4901 #	RN4981 #
		10	10	RN1902 #	RN2902 #	RN4902 #	RN4982 #
		22	22	RN1903 #	RN2903 #	RN4903 #	RN4983 #
		47	47	RN1904 #	RN2904 #	RN4904 #	RN4984 #
		2.2	47	RN1905 #	RN2905 #	RN4905 #	RN4985 #
		4.7	47	RN1906 #	RN2906 #	RN4906 #	RN4986 #
		10	47	RN1907 #	RN2907 #	RN4907 #	RN4987 #
		22	47	RN1908 #	RN2908 #	RN4908 #	RN4988 #
		47	22	RN1909 #	RN2909 #	RN4909 #	RN4989 #
		4.7	-	RN1910 #	RN2910 #	RN4910 #	RN4990 #
10	-	RN1911 #	RN2911 #	RN4911 #	-		
47/2.2*	47	-	-	-	RN49A2		







V _{ce(sat)} (V)	I _c (mA)	SM6 (SOT-26)			
		Resistance			
		R1 typ. (kΩ)	R2 typ. (kΩ)	Part Number	
50	100	 2.9 x 2.8			
		 Point symmetrical		 Point symmetrical	
				NPN x 2	PNP + NPN
		4.7	4.7	RN1601	RN2601
		10	10	RN1602	RN2602
		22	22	RN1603	RN2603
		47	47	RN1604	RN2604
		2.2	47	RN1605	RN2605
		4.7	47	RN1606	RN2606
		10	47	RN1607	RN2607
		22	47	RN1608	RN2608
		47	22	RN1609	-
		4.7	-	RN1610	RN2610
10	-	RN1611	-		
22	-	-	-		

* Q1/Q2
AEC-Q101 qualified

3. Diodes

■ Schottky Barrier Diodes (SBDs)







Package Dimensions (unit: mm)





Features		Absolute Maximum Ratings		Electrical Characteristics (Ta = 25 °C)					CST2 (SOD-882)	CST2B	CST2C (SOD-963)	USC (SOD-323)	US2H (SOD-323HE)	UFV (SOT-353F)									
									Bottom View	Bottom View	Bottom View												
V _r / V _{RM} * (V)	I _o (A)	V _f			I _r max (μA)		C _t typ. (pF)																
		typ. (V)	max (V)	@I _r (A)	max	@V _r (V)		1.0 x 0.6	1.2 x 0.8	1.6 x 0.8	2.5 x 1.25	2.5 x 1.4	2.0 x 2.1										
High-V _r and I _o	60	2	0.52	0.59	2	70	60	300															
			0.46	0.53	2	650	60	290															
		1.5	0.66	0.73	1.5	50	60	130															
			0.6	0.67	1.5	450	60	130															
		1	0.56	0.62	1	40	60	130															
		40	2	0.47	0.54	2	60	40	300														
	0.4			0.47	2	300	40	290															
	1.5		0.45	0.51	1.5	200	40	170															
			0.57	0.63	1.5	50	40	130															
			0.59	0.64	1.5	25	40	130															
	1		to 0.63	to 0.7	1	20	40	74															
	0.5	0.74	0.81	0.5	15	40	28																
40*	1.5	0.47	0.55	1.5	200	40	170																
		to 0.48	to 0.55	1	150	40	120																
	0.5	0.56	0.6	0.5	50	40	42																
	2	0.4	0.47	2	60	30	380																
		0.34	0.41	2	500	30	390																
		0.46	0.52	1.5	50	30	170																
		0.37	0.43	1.5	500	30	200																
	1	0.47	0.57	1	50	30	120																
		0.43	0.5	1	50	30	170																
		0.8	0.4	0.45	0.8	50	30	170															
		0.5	0.38	0.45	0.5	50	30	to 120															
			0.38	0.47	0.5	100	20	-															
30	1.5	0.39	-	1.5	500	30	200																
		to 0.39	0.45	1	500	30	135																
	0.5	0.41	0.47	0.5	300	30	55																
30*	1.5	0.39	-	1.5	500	30	200																
		to 0.39	0.45	1	500	30	135																
	0.5	0.41	0.47	0.5	300	30	55																
	2	0.4	0.47	2	60	30	380																
		0.34	0.41	2	500	30	390																
	1.5	0.46	0.52	1.5	50	30	170																
		0.37	0.43	1.5	500	30	200																
	1	0.47	0.57	1	50	30	120																
		0.43	0.5	1	50	30	170																
		0.8	0.4	0.45	0.8	50	30	170															
		0.5	0.38	0.45	0.5	50	30	to 120															
			0.38	0.47	0.5	100	20	-															
30*	1.5	0.39	-	1.5	500	30	200																
		to 0.39	0.45	1	500	30	135																
	0.5	0.41	0.47	0.5	300	30	55																








■ Schottky Barrier Diodes (SBDs)

Package Dimensions (unit: mm)

Features	Absolute Maximum Ratings		Electrical Characteristics (Ta = 25 °C)						CL2E	CST2 (SOD-882)	SOD-923	ESC (SOD-523)	USC (SOD-323)
	V _R (V)	I _O (A)	V _F			I _R max (μA)		C _t typ. (pF)	Bottom View	Bottom View			
			typ. (V)	max (V)	@I _F (A)	max (μA)	@V _R (V)						
Low-I _F High-Speed	40	1	0.52	0.57	1	25	40	130					
	20	0.05	0.5	0.55	0.05	0.5	20	3.9		1SS413CT	1SS413	1SS405 #	1SS406 #



























Features	Absolute Maximum Ratings		Electrical Characteristics (Ta = 25 °C)						S-Mini (SOT-346)	US6 (SOT-363)
	V _R (V)	I _O (A)	V _F			I _R max (μA)		C _t typ. (pF)		
			typ. (V)	max (V)	@I _F (A)	max (μA)	@V _R (V)		2.9 x 2.5	2.0 x 2.1
Low-I _F High-Speed	20	0.1	0.5	0.55	0.1	0.5	20	3.9		
	10	0.05	0.63	1	0.05	0.5	10	3.2		









Features	Absolute Maximum Ratings		Electrical Characteristics (Ta = 25 °C)						SL2 (SOD-962)	CST2 (SOD-882)	SOD-923	ESC (SOD-523)	USC (SOD-323)
	V _R (V)	I _O (A)	V _F			I _R max (μA)		C _t typ. (pF)	Bottom View	Bottom View			
			typ. (V)	max (V)	@I _F (A)	max (μA)	@V _R (V)						
Standard	40	0.1	0.54	0.6	0.1	5	40	11				CES388 #	CUS357 #
			0.56	0.62	0.1	5	40	15		1SS417CT	1SS417		
	30	0.2	0.52	0.6	0.2	5	30	to 17		CTS520		CES520 #	CUS520 #
			0.45	0.5	0.2	30	30	to 26		CTS521		CES521	CUS521 #
		0.1	0.38	0.5	0.1	50	30	15		1SS416CT	1SS416		
			0.51	0.62	0.1	0.7	30	8.2	DSR01S30SL				
	20	0.41	0.5	0.1	50	30	9.3	DSF01S30SL					
		0.3	0.38	0.45	0.3	50	20	46					1SS404
	10	0.2	0.42	0.5	0.2	50	20	20				1SS424	
		0.1	0.35	0.5	0.1	20	10	20				1SS389 #	1SS367 #

AEC-Q101 qualified

■ Schottky Barrier Diodes (SBDs)

Package Dimensions (unit: mm)


























Features	Absolute Maximum Ratings		Electrical Characteristics (Ta = 25 °C)					VESM (SOT-723)	SSM (SOT-416)	USM (SOT-323)	S-Mini (SOT-346)	SOT23 (SOT-23)							
								V _R (V)	I _O (A)	V _F			I _R max (μA)	C _t typ. (pF)					
										typ. (V)	max (V)	@I _F (A)							
Standard	40	0.1	0.54	0.6	0.1	5	40	18			1SS322 	1SS294 							
			0.54	0.6	0.1	5	40	18			1SS393 	1SS392 							
			0.56	0.62	0.1	5	40	15		1SS423 									
			0.56	0.62	0.1	5	40	15											
	30	0.2	0.45	0.58	0.1	2	25	-					TBAT54 						
													TBAT54C 						
													TBAT54S 						
													TBAT54A 						
		0.1	0.38	0.5	0.1	50	30	15		1SS422 									
	20	0.3	0.38	0.45	0.3	50	20	46			1SS401 								
	10	0.1	0.35	0.5	0.1	20	10	20			1SS395 	1SS394 							
									1SS385FV 	1SS385 	1SS378 	1SS377 							
										1SS372 	1SS374 								

Features	Absolute Maximum Ratings		Electrical Characteristics (Ta = 25 °C)					ESV (SOT-553)	US6 (SOT-363)	SM6 (SOT-26)							
								V _R (V)	I _O (A)	V _F			I _R max (μA)	C _t typ. (pF)			
										typ. (V)	max (V)	@I _F (A)					
Standard	40	0.1	0.54	0.6	0.1	5	40	18	HN2S02JE 	HN2S02FU 							
	20	0.2	0.36	0.42	0.2	50	20	46		HN2S04FU 							
	10	0.1	0.35	0.5	0.1	20	10	20		HN2S01FU 	HN2S01F 						

AEC-Q101 qualified

Switching Diodes

Package Dimensions (unit: mm)





































Absolute Maximum Ratings		Electrical Characteristics (Ta = 25 °C)		CST2 (SOD-882)	SOD-923	ESC (SOD-523)	USC (SOD-323)	CST3 (SOT-883)	VESM (SOT-723)	SSM (SOT-416)	USM (SOT-323)	SOT23 (SOT-23)	
Vr (V)	Io (mA)	Cr typ. (pF)	trr typ. (ns)	Bottom View				Bottom View					
													
80	80	0.5	1.6										
				0.3	1.6		1SS427						
		0.5	1.6	1SS387CT		1SS387 #	1SS352 #						
	100	0.9	1.6										
													
		2	-			1SS307E #							
		2.2	1.6										
	215	0.9	1.6										
													
	100	150	0.9	4 (max)									
4 (max)													
215		0.9	3 (max)										
			0.35	3 (max)		BAS516	BAS316						
	0.5	3 (max)			1N4148WT☆	1N4148WS☆							
200	100	1.5	10										
			60 (max)			1SS403E							
400	100	2.5	0.5										

AEC-Q101 qualified
 ☆ New Products

- 1 MOSFETS
- 2 Tr./BRTs
- 3 Diodes
- 4 Power Management ICs
- 5 Linear ICs
- 6 Sensors
- 7 General Purpose Logic ICs
- 8 RF Devices
- 9 Packages

Switching Diodes









Package Dimensions (unit: mm)

Absolute Maximum Ratings		Electrical Characteristics (Ta = 25 °C)		S-Mini (SOT-346)	ESV (SOT-553)	USV (SOT-353)	SMV (SOT-25)	ES6 (SOT-563)	US6 (SOT-363)	SM6 (SOT-26)	
V _R (V)	I _o (mA)	C _t typ. (pF)	t _{rr} typ. (ns)								
30	100	3	-	2.9 x 2.5 	1.6 x 1.6	2.0 x 2.1	2.9 x 2.8	1.6 x 1.6	2.0 x 2.1	2.9 x 2.8	
80	80	0.5	1.6						HN2D01FU # 	HN2D01F 	
									HN2D02FU # 		
	100	0.5	1.6		HN2D01JE 						
					1SS184 # 	HN4D02JU 	1SS309 				
		0.9	1.6		1SS226 # 				HN1D02FE 	HN1D02FU # 	HN1D02F 
					1SS196 # 						
					1SS193 # 						
					1SS190 # 	HN4D01JU 	1SS308 				
		2.2	1.6		1SS187 # 				HN1D01FE 	HN1D01FU # 	HN1D01F 
					1SS181 # 						
	1SS379 # 										
	Q1/2=0.9 Q3/4=2.2	1.6						HN1D03FU # 	HN1D03F 		
200	100	1.5	10	1SS250 							
400	100	2.5	0.5	1SS398 						HN2D03F 	
		4.3	0.5					HN1D05FE ☆ 			

☆ New Products
AEC-Q101 qualified

TVS Diodes (ESD Protection Diodes)

Package Dimensions (unit: mm)

Application	Absolute Maximum Ratings		Electrical Characteristics (Ta = 25 °C)			SL2 (SOD-962)	CST2 (SOD-882)	SOD-923	ESC (SOD-523)	
						Bottom View 	Bottom View 			
						0.62 x 0.32	1.0 x 0.6	1.0 x 0.6	1.6 x 0.8	
	V _{ESD} IEC61000 -4.2 (kV)	I _{PP} tp = 8 / 20 μs (A)	V _{RWM} max (V)	C _t typ. (pF)	R _{DYM} typ. (Ω)					
Bi-directional	USB3.1 / Thunderbolt™ / RF antenna	±20	2.5	3.3	0.3	0.5	DF2B5M5SL	DF2B5M5CT		
		±20	2.5	5	0.3	0.5	DF2B6M5SL	DF2B6M5CT		
		±20	2	3.6	0.2	0.5 to 0.8	DF2B5M4SL	DF2B5M4CT		
		±20	2	5.5	0.2	0.5 to 0.8	DF2B6M4SL	DF2B6M4CT		
		±16	2	3.6	0.15	0.7	DF2B5M4ASL			
		±15	2	5.5	0.15	0.7	DF2B6M4ASL			
		±15	1	11	0.2	0.65	DF2B12M4SL			
		±15	0.5	18.5	0.2	0.2	DF2B20M4SL			
		±15	0.5	24	0.2	0.2	DF2B26M4SL			
		±12	2.5	5.5	0.1	0.7	DF2B7M3SL			
	±12	2	5	0.2	1	DF2B7M2SL ●				
	±12	2.5	5	0.3	0.8		DF2B6.8M1ACT			
	±8	2	5.5	0.12	0.7	DF2B6M4BSL				
	USB2.0	±10	1.5	5.5	1.5	0.25	DF2B6USL			
	General Purpose / Audio / SIM Card	±30	27	5.5	45	0.1		DF2B7PCT		
±30		4	5.5	8.5	0.2	DF2B7ASL	DF2B7ACT	DF2B7AFS #	DF2B7AE	
±30		7.3	5.5	12	0.2	DF2B7BSL				
±30		27	3.6	41	0.1		DF2B5PCT			
±23		8	3.3	11	0.2	DF2B5BSL				
±17		3	5.3	6	0.3	DF2B7SL				
±17		5.5	3.3	7.2	0.25	DF2B5SL				
	±8	-	5	15	-				DF2B6.8E #	
Uni-directional	USB3.1 / Thunderbolt™ / RF antenna (NFC)	±20	2	3.6	0.35 to 0.45	0.3 to 0.35	DF2S5M4SL	DF2S5M4CT	DF2S5M4FS ☆ #	
		±20	2	5.5	0.35 to 0.45	0.3 to 0.35	DF2S6M4SL	DF2S6M4CT	DF2S6M4FS ☆ #	
		±20	2.5	3.3	0.6	0.3	DF2S5M5SL	DF2S5M5CT		
		±20	2.5	5	0.6	0.3	DF2S6M5SL	DF2S6M5CT		
	USB2.0	±12	3	5	to 0.5	0.35	DF2S7MSL ●		DF2S6.8MFS	
	General Purpose / Audio / SIM Card	±30	2.5	1.5	45	0.2	DF2S5.1ASL			
		±30	2.5	3.5	40	0.25	DF2S5.6ASL			
		±30	2.5	5	32	0.3	DF2S6.2ASL			
		±30	2.5	5	25	0.5	DF2S6.8ASL			
		±30	2.5	6.5	20	0.8	DF2S8.2ASL			
		±30	2.5	8	16	0.5	DF2S10ASL ☆			
		±20	2.5	9	13	1.5	DF2S12ASL ☆			
		±12	2.5	12	10	0.6	DF2S16ASL			
		±12	2.5	15	9.5	1.25	DF2S20ASL ☆			
		±10	2.5	19	8.5	1.5	DF2S24ASL ☆			
±8		2.5	23	7.5	4	DF2S30ASL ☆				

Thunderbolt™ is a trademark of Intel Corporation or its subsidiaries.

☆ New Products, # AEC-Q101 qualified




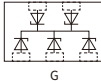
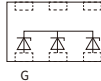
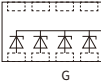
● Recommended Another New Product




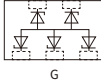

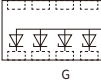
DF2S7MSL → DF2S6M5SL, DF2B7M2SL → DF2B6M4SL









- ① MOSFETS
- ② Tr./BRTS
- ③ Diodes
- ④ Power Management ICs
- ⑤ Linear ICs
- ⑥ Sensors
- ⑦ General Purpose Logic ICs
- ⑧ RF Devices
- ⑨ Packages

TVS Diodes (ESD Protection Diodes)

Package Dimensions (unit: mm)

Application		Absolute Maximum Ratings		Electrical Characteristics (Ta = 25 °C)			DFN5	DFN6	DFN10
							Bottom View	Bottom View	Bottom View
							 1.3 x 0.8	 1.25 x 1.0	 2.5 x 1.0
Bi-directional	USB3.1 / Thunderbolt™ / RF antenna	V _{ESD} IEC61000 -4-2 (kV)	I _{PP} tp = 8 / 20 μs (A)	V _{RWM} max (V)	C _t typ. (pF)	R _{DYN} typ. (Ω)	 G	 G	 G
		±20	2	3.6	0.2	0.5 to 0.8	DF5G5M4N	DF6D5M4N	DF10G5M4N
		±20	2	5.5	0.2	0.5 to 0.8	DF5G6M4N	DF6D6M4N	DF10G6M4N







Application		Absolute Maximum Ratings		Electrical Characteristics (Ta = 25 °C)			DFN5	DFN6	DFN10
							Bottom View	Bottom View	Bottom View
							 1.3 x 0.8	 1.25 x 1.0	 2.5 x 1.0
Bi-directional	USB3.1 / Thunderbolt™ / RF antenna	V _{ESD} IEC61000 -4-2 (kV)	I _{PP} tp = 8 / 20 μs (A)	V _{RWM} max (V)	C _t typ. (pF)	R _{DYN} typ. (Ω)	 G	 G	 G
		±12	2.5	5.5	0.2	1	DF5G7M2N		
		±8	-	5	0.3	0.9		DF6D7M1N	
		±8	-	5	0.3	0.9		DF10G7M1N	

















Application		Absolute Maximum Ratings		Electrical Characteristics (Ta = 25 °C)			USC (SOD-323)	SSM (SOT-416)	USM (SOT-323)	UDFN6B (SOT-1220)
							Bottom View	Bottom View	Bottom View	Bottom View
							 2.5 x 1.25	 1.6 x 1.6	 2.0 x 2.1	 2.0 x 2.0
Bi-directional	General Purpose / Audio / SIM Card	±30	4	5.5	8.5	0.2				
	Automotive's CAN/LIN	±30	2.5	12	9	0.8	DF2B18FU #		DF3D18FU #	
		±25	3	24	9	1.1	DF2B29FU #		DF3D29FU #	
		±20	2.5	28	6.5	1.5	DF2B36FU #		DF3D36FU #	
Uni-directional	USB2.0	±8	-	5	0.5	-		DF3D6.8MS		
	Power Supply USB_V _{BUS}	±30	80	5.5	600	0.08	DF2S6P2FU			
		±30	60	10	280	0.08	DF2S12P2FU ☆			
		±30	50	12.6	270	0.08	DF2S14P2FU			
		±30	14	21	160	0.13	DF2S23P2FU			
		±30	110	22	-	0.01				DF6S25P3NU ☆

Thunderbolt™ is a trademark of Intel Corporation or its subsidiaries.
 ☆ New Products, # AEC-Q101 qualified

■ TVS Diodes (ESD Protection Diodes)

Package Dimensions (unit: mm)

Application	Absolute Maximum Ratings	Electrical Characteristics (Ta = 25 °C)			CST2	SOD-923	USC
					(SOD-882)	(SOD-323)	(SOD-323)
					Bottom View		
							
				1.0 x 0.6	1.0 x 0.6	2.5 x 1.25	
	V _{ESD} IEC61000 -4.2 (kV)	V _Z min (V)	C _T typ. (pF)	Z _Z max (Ω)			
Uni-directional General-Purpose/ SIM Card/ Power-Supply	±30	4.8	45	70		DF2S5.1FS #	
	±30	5.3	40	30	DF2S5.6CT	DF2S5.6FS #	
	±30	5.8	32	30	DF2S6.2CT	DF2S6.2FS #	
	±30	6.4	25	30	DF2S6.8CT	DF2S6.8FS #	
	±30	7.7	20	30	DF2S8.2CT	DF2S8.2FS #	
	±30	9.4	16	30		DF2S10FS #	
	±20	11.4	15	10 (typ.)			DF2S12FU
	±20	11.4	15	25		DF2S12FS #	
	±12	15.3	10	35	DF2S16CT	DF2S16FS #	
	±12	18.8	9	to 55	DF2S20CT	DF2S20FS #	
	±10	22.8	8.5	70		DF2S24FS #	
±8	28	7.2	75	DF2S30CT			
±8	28	7	150		DF2S30FS #		






Application	Absolute Maximum Ratings	Electrical Characteristics (Ta = 25 °C)			CST3	VESM	USM	S-Mini	ESV	USV	SMV	US6
					(SOT-883)	(SOT-723)	(SOT-323)	(SOT-346)	(SOT-553)	(SOT-353)	(SOT-25)	(SOT-363)
					Bottom View							
												
				1.0 x 0.6	1.2 x 1.2	2.0 x 2.1	2.9 x 2.5	1.6 x 1.6	2.0 x 2.1	2.9 x 2.8	2.0 x 2.1	
	V _{ESD} IEC61000 -4.2 (kV)	V _Z min (V)	C _T typ. (pF)	Z _Z max (Ω)								
Uni-directional General-Purpose/ SIM Card/ Power-Supply	±30	5.3	65	40		DF3A5.6FV #	DF3A5.6FU	DF3A5.6F	DF5A5.6JE	DF5A5.6FU	DF5A5.6F	
	±30	5.8	55	30		DF3A6.2FV #	DF3A6.2FU	DF3A6.2F	DF5A6.2JE	DF5A6.2FU	DF5A6.2F	
	±30	6.4	45	25	DF3A6.8CT	DF3A6.8FV #	DF3A6.8FU	DF3A6.8F	DF5A6.8JE	DF5A6.8FU	DF5A6.8F	DF6A6.8FU
	±30	5.3	29	40					DF5A5.6CJE	DF5A5.6CFU		
	±30	5.8	25	30					DF5A6.2CJE	DF5A6.2CFU		
	±25	6.4	23	25					DF5A6.8CJE	DF5A6.8CFU		
	±8	5.3	8	50			DF3A5.6LFU		DF5A5.6LJE	DF5A5.6LFU		
	±8	5.3	8	3 (typ.)			DF3A5.6LFV #					
	±8	5.9	6.5	50			DF3A6.2LFV #	DF3A6.2LFU	DF5A6.2LJE	DF5A6.2LFU		
	±8	6.5	to 6	50	DF3A6.8LCT	DF3A6.8LFV #	DF3A6.8LFU		DF5A6.8LJE	DF5A6.8LFU	DF5A6.8LF	

AEC-Q101 qualified



Zener Diodes for Over Voltage Protection

Package Dimensions (unit: mm)

General type

Application	Electrical Characteristics (Ta = 25 °C)					ESC (SOD-523)	USC (SOD-323)	USM (SOT-323)	S-Mini (SOT-346)	SOT23 (SOT-23)	
											
	Vz typ. (V)	Vz Range (V)	Iz (mA)	Ir max (µA)	Vr (V)	Po = 150 mW*	Po = 200 mW*	Po = 150 mW*	Po = 200 mW*	Po = 320 mW*	
Uni-directional	5.6	5.3 to 6	5	1	3.5	CEZ5V6 ☆	CUZ5V6	MUZ5V6 ☆	MSZ5V6 ☆	MKZ5V6 ☆	
	6.2	5.8 to 6.6	5	2.5	5	CEZ6V2 ☆	CUZ6V2 ☆	MUZ6V2 ☆	MSZ6V2 ☆	MKZ6V2 ☆	
	6.8	6.4 to 7.2	5	1.5	5.5	CEZ6V8 ☆	CUZ6V8	MUZ6V8 ☆	MSZ6V8 ☆	MKZ6V8 ☆	
	7.5	7 to 7.9	5	0.1	6	CEZ7V5 ☆	CUZ7V5 ☆	MUZ7V5 ☆	MSZ7V5 ☆	MKZ7V5 ☆	
	8.2	7.7 to 8.7	5	0.1	7	CEZ8V2 ☆	CUZ8V2	MUZ8V2 ☆	MSZ8V2 ☆	MKZ8V2 ☆	
	9.1	8.5 to 9.6	5	0.1	7.5	CEZ9V1 ☆	CUZ9V1 ☆	MUZ9V1 ☆	MSZ9V1 ☆	MKZ9V1 ☆	
	10	9.4 to 10.6	5	0.1	8	CEZ10V ☆	CUZ10V ☆	MUZ10V ☆	MSZ10V ☆	MKZ10V ☆	
	11	10.4 to 11.6	5	0.1	9	CEZ11V ☆	CUZ11V ☆	MUZ11V ☆	MSZ11V ☆	MKZ11V ☆	
	12	11.4 to 12.6	5	0.1	10	CEZ12V ☆	CUZ12V	MUZ12V ☆	MSZ12V ☆	MKZ12V ☆	
	13	12.4 to 14.1	5	0.1	11	CEZ13V ☆	CUZ13V ☆	MUZ13V ☆	MSZ13V ☆	MKZ13V ☆	
	General-Purpose / SIM Card / Power-Supply	15	13.8 to 15.6	5	0.1	12	CEZ15V ☆	CUZ15V ☆	MUZ15V ☆	MSZ15V ☆	MKZ15V ☆
		16	15.3 to 17.1	5	0.1	14	CEZ16V ☆	CUZ16V	MUZ16V ☆	MSZ16V ☆	MKZ16V ☆
		18	16.8 to 19.1	5	0.1	16	CEZ18V ☆	CUZ18V ☆	MUZ18V ☆	MSZ18V ☆	MKZ18V ☆
		20	18.8 to 21.2	5	0.1	17.6	CEZ20V ☆	CUZ20V	MUZ20V ☆	MSZ20V ☆	MKZ20V ☆
		22	20.8 to 23.3	5	0.1	18	CEZ22V ☆	CUZ22V ☆	MUZ22V ☆	MSZ22V ☆	MKZ22V ☆
		24	22.8 to 25.6	5	0.1	19	CEZ24V ☆	CUZ24V	MUZ24V ☆	MSZ24V ☆	MKZ24V ☆
		27	25.1 to 28.9	2	0.1	23	CEZ27V ☆	CUZ27V ☆	MUZ27V ☆	MSZ27V ☆	MKZ27V ☆
		30	28 to 32	2	0.1	27	CEZ30V ☆	CUZ30V	MUZ30V ☆	MSZ30V ☆	MKZ30V ☆
		33	31 to 35	2	0.1	30	CEZ33V ☆	CUZ33V ☆	MUZ33V ☆	MSZ33V ☆	MKZ33V ☆
		36	34 to 38	2	0.1	32.5	CEZ36V ☆	CUZ36V	MUZ36V ☆	MSZ36V ☆	MKZ36V ☆

General type (For Automotive)



Application	Electrical Characteristics (Ta = 25 °C)					USC	
							Po = 200 mW*
	Vz typ. (V)	Vz Range (V)	Iz (mA)	Ir max (µA)	Vr (V)		
Uni-directional	5.6	5.3 to 6	5	1	2.5	XCUZ5V6 ☆ #	
	6.2	5.8 to 6.6	5	1	3	XCUZ6V2 ☆ #	
	6.8	6.4 to 7.2	5	0.5	3.5	XCUZ6V8 ☆ #	
	7.5	7 to 7.9	5	0.5	4	XCUZ7V5 ☆ #	
	8.2	7.7 to 8.7	5	0.1	5	XCUZ8V2 ☆ #	
	9.1	8.5 to 9.6	5	0.1	6	XCUZ9V1 ☆ #	
	10	9.4 to 10.6	5	0.1	7	XCUZ10V ☆ #	
	11	10.4 to 11.6	5	0.1	8	XCUZ11V ☆ #	
	12	11.4 to 12.6	5	0.1	9	XCUZ12V ☆ #	
	General-Purpose / SIM Card / Power-Supply	13	12.4 to 14.1	5	0.1	10	XCUZ13V ☆ #
		15	13.8 to 15.6	5	0.1	11	XCUZ15V ☆ #
		16	15.3 to 17.1	5	0.1	12	XCUZ16V ☆ #
		18	16.8 to 19.1	5	0.1	13	XCUZ18V ☆ #
		20	18.8 to 21.2	5	0.1	15	XCUZ20V ☆ #
		22	20.8 to 23.3	5	0.1	17	XCUZ22V ☆ #
		24	22.8 to 25.6	5	0.1	19	XCUZ24V ☆ #
		27	25.1 to 28.9	2	0.1	21	XCUZ27V ☆ #
		30	28 to 32	2	0.1	23	XCUZ30V ☆ #
		33	31 to 35	2	0.1	25	XCUZ33V ☆ #
		36	34 to 38	2	0.1	27	XCUZ36V ☆ #

☆ New Products



* Please refer to the data sheet for the conditions of the measurement board.

AEC-Q101 qualified

Power type

Application	Electrical Characteristics (Ta = 25 °C)					US2H (SOD-323HE)
						 2.5 x 1.4 Po = 500 mW*
	Vz typ. (V)	Vz Range (V)	Iz (mA)	Ir max (µA)	Vr (V)	
Uni-directional General-Purpose/ SIM Card / Power-Supply	5.6	5.3 to 6	10	10	3.5	CUHZ5V6
	6.2	5.8 to 6.6	10	10	5	CUHZ6V2
	6.8	6.4 to 7.2	10	0.5	5.5	CUHZ6V8
	8.2	7.7 to 8.7	10	0.1	7	CUHZ8V2
	12	11.4 to 12.6	10	0.1	10	CUHZ12V
	16	15.3 to 17.1	10	0.1	14	CUHZ16V
	20	18.8 to 21.2	10	0.1	17.6	CUHZ20V
	24	22.8 to 25.6	10	0.1	19	CUHZ24V
	30	28 to 32	10	0.1	27	CUHZ30V
36	34 to 38	9	0.1	32.5	CUHZ36V	

Ultra Small type

Application	Electrical Characteristics (Ta = 25 °C)					SL2 (SOD-962)
						 0.62 x 0.32 Po = 150 mW*
	Vz typ. (V)	Vz Range (V)	Iz (mA)	Ir max (µA)	Vr (V)	
Uni-directional General-Purpose/ SIM Card / Power-Supply	5.6	5.3 to 6	5	1	3.5	CSLZ5V6 ☆
	6.2	5.8 to 6.6	5	2.5	5	CSLZ6V2 ☆
	6.8	6.4 to 7.2	5	0.5	5	CSLZ6V8 ☆
	8.2	7.7 to 8.7	5	0.5	6.5	CSLZ8V2 ☆
	10	9.4 to 10.6	5	0.5	8	CSLZ10V ☆
	12	11.4 to 12.6	5	0.5	9	CSLZ12V ☆
	16	15.3 to 17.1	5	0.5	12	CSLZ16V ☆
	20	18.8 to 21.2	5	0.5	15	CSLZ20V ☆
	24	22.8 to 25.6	5	0.5	19	CSLZ24V ☆
30	28 to 31.5	2	0.5	23	CSLZ30V ☆	

☆ New Products

* Please refer to the data sheet for the conditions of the measurement board.

■ Part Naming Conventions

Diode (JEITA Registration Products)

1 S S 181

- Serial number: JEITA registration number.
- The kind of diode
 - S: Diode of general-purpose use, detection use, frequency conversion use, and switching use
 - V: Variable capacitance and PIN diode
- S stands for Semiconductor
- The value that subtracted 1 from the total number of terminals

Schottky Barrier Diodes

New Naming Conventions

CU S 05 F 30 A

- Revision or function category (A to Z)
- Voltage rating
 - Ex.) 30: 30 V
- Device type
 - Ex.) S: Super Low forward voltage F: Low forward voltage, R: Low leakage current
- Current rating
 - Ex.) 05: 0.5 A
- Pin count
 - Ex.) S: 2pin
- Package
 - Ex.) CU: USC, CE: ESC, CB: CST2B, CE: CL2E

Old Naming Conventions

DS F 07 S 30 A U

- Package style: This letter shows the package style.
- Revision
- Voltage rating
 - Ex.) 30: 30 V, 15: 15 V
- Circuit configuration and number of pins
- Current rating
 - Ex.) 07: 0.7 A, 10: 1 A
- Device feature: This letter shows the feature of a device.
 - F: Low forward voltage type.
 - R: Low leakage current type.
- Schottky barrier diode.

TVS Diodes (ESD Protection Diodes)

DF 5 A 6.2 L FU

- Package suffix
- Series name
 - Ex.) L: Ultra-high-speed
- Reverse Breakdown Voltage (V_{BR})
- Internal configuration
 - Ex.) A: Common anode
- Pin count
- TVS Diodes (ESD Protection Diodes)

Zener Diodes for Over Voltage Protection

CU Z 6V8

- Zener voltage
 - Ex.) 6V8: 6.8 V
- The kind of diode
 - Z: Zener Diode (uni-directional type)
- Package

CU: USC	MS: S-Mini	CSL: SL2
CUH: US2H	MU: USM	
CE: ESC	MK: SOT23	

Note: The name of AEC-Q100 qualified product is XCZUxxx.

4. Power Management ICs

Low Dropout Regulators (LDO)

Package Dimensions (unit: mm)

WCSP4E	WCSP4F	SDFN4E	DFN4D	DFN4E	DFN4F	DFN5B	ESV (SOT-553)	UFV (SOT-353F)	SMV (SOT-25)	WCSP6F
Bottom View	Bottom View	Bottom View	Bottom View	Bottom View	Bottom View	Bottom View				Bottom View
0.645 x 0.645	0.645 x 0.645	0.8 x 0.8	1.0 x 1.0	1.0 x 1.0	1.0 x 1.0	1.2 x 1.2	1.6 x 1.6	2.0 x 2.1	2.9 x 2.8	1.2 x 0.8

CMOS LDO Regulators

Series Name / Part Number	Package	V _{OUT} typ. (V)	V _{IN} (V)	I _{OUT} (mA)	I _B typ. (µA)	Function							
						Over current protection	Auto discharge	Fast load transient response circuit	Thermal shutdown	Inrush current protection	Under voltage lockout	High PSRR	Control pin connection
TCR1HFxxB ☆	SMV	1.8 to 5	V _{OUT} +1 to 36	150	1	✓	✓ (A version)	✓	✓	✓			Pull up
TCR2ENxxx	SDFN4E	1 to 3.6	1.5 to 5.5	200	35	✓	✓	✓					Pull down
TCR2LNxxx		0.8 to 3.6	1.5 to 5.5	200	1	✓	✓						Pull down
TCR2EExxx	ESV	1 to 5	1.5 to 5.5	200	35	✓	✓	✓					Pull down
TCR2LExxx		0.8 to 3.6	1.5 to 5.5	200	1	✓	✓						Pull down
TCR2EFxxx	SMV	1 to 5	1.5 to 5.5	200	35	✓	✓	✓					Pull down
TCR2LFxxx		0.8 to 3.6	1.5 to 5.5	200	1	✓	✓						Pull down
TCR3DGxxx	WCSP4E	1 to 4.5	1.75 to 5.5	300	65	✓	✓	✓	✓	✓			Pull down
TCR3LMxxA ☆	DFN4D	0.8 to 5	1.4 to 5.5	300	1.2	✓	✓		✓				Pull down
TCR3DMxxA ☆		1 to 4.5	1.5 to 5.5	300	86	✓	✓		✓				Pull down
TCR3EMxxA ★		0.8 to 5	1.3 to 5.5	300	35	✓	✓		✓				Pull down
TCR3DMxxx	DFN4E	1 to 4.5	1.75 to 5.5	300	65	✓	✓	✓	✓	✓			Pull down
TCR3DFxxx	SMV	1 to 4.5	1.8 to 5.5	300	65	✓	✓	✓	✓	✓			Pull down
TCR3UGxxxA	WCSP4F	0.8 to 5	1.5 to 5.5	300	0.34	✓	✓	✓	✓	✓			Pull down
TCR3UGxxxB		1.5 to 5.5	300	0.34	✓	✓	✓	✓	✓				Pull down
TCR3UMxxxA	DFN4E	0.8 to 5	1.5 to 5.5	300	0.34	✓	✓	✓	✓	✓			Pull down
TCR3UFxxxA	SMV	0.8 to 5	1.5 to 5.5	300	0.34	✓	✓	✓	✓	✓			Pull down
TCR3UFxxxB		1.5 to 5.5	300	0.34	✓	✓	✓	✓	✓				Pull down
TCR3RMxxxA	DFN4F	0.9 to 4.5	1.8 to 5.5	300	7	✓	✓	✓	✓	✓		✓	Pull down
TCR4DGxxx	WCSP4E	1 to 4.5	V _{OUT} +V _{DD} to 5.5	420	65	✓	✓	✓	✓	✓			Pull down
TCR5RGxxxA	WCSP4F	0.9 to 5	1.8 to 5.5	500	7	✓	✓	✓	✓	✓		✓	Pull down
TCR5BMxxxA	DFN5B	0.8 to 3.6	V _{OUT} +V _{DD} to V _{BIAS}	500	19	✓	✓	✓	✓	✓	✓	✓	Pull down
TCR8BMxxxA		0.8 to 3.6	V _{OUT} +V _{DD} to V _{BIAS}	800	20	✓	✓	✓	✓	✓	✓	✓	Pull down
TCR13AGADJ	WCSP6F	0.55 to 3.6 adjustable	V _{OUT} +0.1 V to V _{BIAS}	1300	56	✓	✓	✓	✓	✓	✓	✓	Pull down
TCR15AGxxx	WCSP6F	0.65 to 3.6	V _{OUT} +V _{DD} to V _{BIAS}	1500	25	✓	✓	✓	✓	✓	✓	✓	Pull down
TCR15AGADJ	WCSP6F	0.6 to 3.6 adjustable	V _{OUT} +V _{DD} to V _{BIAS}	1500	25	✓	✓	✓	✓	✓	✓	✓	Pull down

Bipolar LDO Regulators








Series Name	Package	V _{OUT} typ. (V)	V _{IN} (V)	I _{OUT} (mA)	I _B typ. (µA)	Function				
						Over current protection	Auto discharge	Fast load transient response circuit	Thermal shutdown	Control pin connection
TAR5SxxU	UFV	1.5 to 5	2.4 to 15	200	170	✓			✓	
TAR5Sxx	SMV	1.5 to 5	2.4 to 15	200	170	✓			✓	
TAR5SBxx						✓			✓	

☆ New Products

★ Under development (The specification is subject to change without notice.)

Load Switch ICs

Package Dimensions (unit: mm)

WCSP4D	WCSP4C	SMV (SOT-25)	WCSP6C	WCSP6E	DFN4A	WCSP4G
Bottom View 	Bottom View 		Bottom View 	Bottom View 	Bottom View 	Bottom View 
0.79 x 0.79	0.9 x 0.9	2.9 x 2.8	1.5 x 1.0	1.2 x 0.8	1.2 x 1.2	0.645 x 0.645

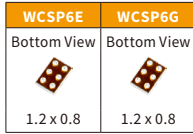
Part Number	Package	Operating voltage range (V)	Output current (A)	R _{DS(on)} (1) Typ. (mΩ)	R _{DS(on)} (2) Typ. (mΩ)	Function						Note				
						Inrush current reduction (Slew Rate control)	Thermal shutdown	Over current protection	Auto discharge	Under voltage lockout	Reverse current block		Control pin connection (Active Level)			
TCK106AG	WCSP4D	1.1 to 5.5	1	176 @1.1V, -0.2A	34 @5V, -0.5A	✓						Pull down (H)				
TCK107AG						✓			✓				Pull down (H)			
TCK108AG						✓			✓				Open (L)			
TCK106AF	SMV	1.1 to 5.5	1	223 @1.1V, -0.2A	63 @5V, -0.5A	✓						Pull down (H)				
TCK107AF						✓			✓			Pull down (H)				
TCK108AF						✓			✓			Open (L)				
TCK111G ★	WCSP6C	1.1 to 5.5	3	8.5 @1.1V, -1.5A	8.3 @5V, -1.5A	✓	✓				True Reverse Current Blocking	Pull down (H)				
TCK112G ★						✓	✓			✓	Pull down (H)					
TCK126BG ☆	WCSP4G	1 to 5.5	1	343 @1V, -0.05A	46 @5V, -0.5A	✓						Pull down (H)	Ultra small Iq 0.08 nA			
TCK127BG ☆						✓			✓			Pull down (H)				
TCK128BG ☆						✓			✓			Open (L)				
TCK22921G	WCSP6E	1.1 to 5.5	2	136 @1.1V, -0.5A	25 @5V, -0.5A	4.5 μs			✓		✓	Pull down (H)				
TCK22922G						666 μs			✓	✓	Pull down (H)					
TCK22923G						1364 μs			✓	✓	Pull down (H)					
TCK22925G						3380 μs			✓	✓	Pull down (H)					
TCK22971G						4.5 μs			✓	✓	Pull down (H)					
TCK22972G						666 μs			✓	✓	Pull down (H)					
TCK22973G						1364 μs			✓	✓	Pull down (H)					
TCK22974G						3380 μs			✓	✓	Pull down (H)					
TCK22975G						666 μs			✓	✓	Open (L)					
TCK22910G						WCSP6E	1.1 to 5.5	2	179 @1.1V, -0.15A	31 @5V, -0.15A	1400 μs	✓			✓	True Reverse Current Blocking
TCK22911G	1400 μs	✓		✓	✓						Open (L)					
TCK22912G	1400 μs	✓		✓	✓						Pull down (H)					
TCK22913G	1400 μs	✓		✓	✓						Pull down (H)					
TCK22946G	WCSP6E	1.1 to 5.5	0.4	179 @1.1V, -0.15A	31 @5V, -0.15A	50 μs	✓	400 mA	✓	✓	True Reverse Current Blocking	Pull down (H)				
TCK22951G			0.74			50 μs	✓	740 mA	✓	✓	Pull down (H)					
TCK2065G		1.11	50 μs			✓	1110 mA	✓	✓	Pull down (H)						
TCK1024G		1.54	50 μs			✓	1540 mA	✓	✓	Pull down (H)						
TCK22891G		1.4 to 5.5	0.4			50 μs	✓	400 mA	✓	✓	Pull down (H)					
TCK22892G		0.74	50 μs			✓	740 mA	✓	✓	Pull down (H)						
TCK22893G		1.11	50 μs			✓	1110 mA	✓	✓	Pull down (H)						
TCK22894G		1.54	50 μs			✓	1540 mA	✓	✓	Pull down (H)						
TCK206G ★		WCSP4C	0.75 to 3.6			2	18.4 @0.75V, -1.5A	18.1 @3.3V, -1.5A	✓					✓	Pull down (H)	
TCK207G ★									✓			✓	✓	Pull down (H)		
TCK208G ★				✓				✓	✓	Open (L)						
TCK207AN	DFN4A			21.5 @0.75V, -1.5A	21.5 @3.3V, -1.5A	✓					✓	Pull down (H)				

☆ New Products

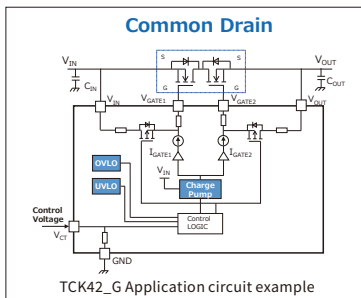
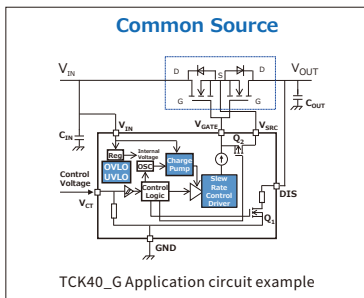
★ Under Development (The specification is subject to change without notice.)

N-ch MOSFET Gate driver ICs with OVP function

Package Dimensions (unit: mm)



Part Number	Package	Operating voltage range (V)	Input quiescent current (ON state)	Gate drive voltage (1)	Gate drive voltage (2)	Function					Note	
						Inrush current reduction	Under voltage lockout	Over voltage lock out (Typ.)	Auto discharge	Reverse current block		Control pin connection (Active Level)
TCK401G	WCSP6E	2.7 to 28	121 μ A typ. @V _{IN} = 5V	4V typ. @V _{IN} = 3V	6.5V typ. @V _{IN} = 5V	✓	✓	✓ (28V)	✓	Option (with external Back to Back MOSFET)	Pull down (H)	For N-ch Common Source MOSFET or Single High Side MOSFET
TCK402G											Pull down (L)	
TCK420G ☆	WCSP6G	2.7 to 28	220 μ A typ. @V _{IN} = 20V	9.2V typ. @V _{IN} = 2.7V	10V typ. @V _{IN} = 24V	✓	✓	✓ (27.73V)		Option (with external Back to Back MOSFET)	Pull down (H)	For N-ch Common Drain MOSFET or Single High Side MOSFET Recommended V _{IN} = 24V
TCK421G ☆	WCSP6G	2.7 to 28	220 μ A typ. @V _{IN} = 20V	9.2V typ. @V _{IN} = 2.7V	10V typ. @V _{IN} = 20V	✓	✓	✓ (23.26V)		Option (with external Back to Back MOSFET)	Pull down (H)	For N-ch Common Drain MOSFET or Single High Side MOSFET Recommended V _{IN} = 20V
TCK422G ☆	WCSP6G	2.7 to 28	185 μ A typ. @V _{IN} = 12V	9.2V typ. @V _{IN} = 2.7V	10V typ. @V _{IN} = 12V	✓	✓	✓ (14.29V)		Option (with external Back to Back MOSFET)	Pull down (H)	For N-ch Common Drain MOSFET or Single High Side MOSFET Recommended V _{IN} = 12V
TCK423G ☆	WCSP6G	2.7 to 28	140 μ A typ. @V _{IN} = 12V	5.6V typ. @V _{IN} = 2.7V	5.6V typ. @V _{IN} = 12V	✓	✓	✓ (14.29V)		Option (with external Back to Back MOSFET)	Pull down (H)	For N-ch Common Drain MOSFET or Single High Side MOSFET Recommended V _{IN} = 12V
TCK424G ☆	WCSP6G	2.7 to 28	125 μ A typ. @V _{IN} = 9V	5.6V typ. @V _{IN} = 2.7V	5.6V typ. @V _{IN} = 9V	✓	✓	✓ (10.83V)		Option (with external Back to Back MOSFET)	Pull down (H)	For N-ch Common Drain MOSFET or Single High Side MOSFET Recommended V _{IN} = 9V
TCK425G ☆	WCSP6G	2.7 to 28	100 μ A typ. @V _{IN} = 5V	5.6V typ. @V _{IN} = 2.7V	5.6V typ. @V _{IN} = 5V	✓	✓	✓ (6.31V)		Option (with external Back to Back MOSFET)	Pull down (H)	For N-ch Common Drain MOSFET or Single High Side MOSFET Recommended V _{IN} = 5V



☆ New Products

1 MOSFETs

2 Tr./BRTs

3 Diodes

4 Power Management ICs

5 Linear ICs

6 Sensors



7 General Purpose Logic ICs

8 RF Devices

9 Packages




■ Power Multiplexer ICs

Package Dimensions (unit: mm)

WCSP9	WCSP16C
Bottom View 	Bottom View 
1.5 x 1.5	1.9 x 1.9

Part Number	Package	Operating voltage range (V)	Output current (A)	R _{DS(on)} typ. (mΩ) @Ta = 25 °C	R _{DS(on)} max (mΩ) @Ta = -40 to 85 °C	Function							Flag Operation Monitored input	Note
						Inrush current reduction	Thermal shutdown	Under voltage lockout	Over voltage lockout	Auto discharge	Reverse current block	Control pin connection (Active Level)		
TCK301G	WCSP9	2.3 to 28	3	73 @4.5 V, -1 A	140 @4.5 V, -1 A	✓	✓	✓	6.6 V		✓	Pull up (H)	-	Single input Single output
TCK302G						✓	✓	✓	10.5 V	✓	-			
TCK303G						✓	✓	✓	15.5 V	✓	-			
TCK304G						✓	✓	✓	6.6 V	✓	-			
TCK305G						✓	✓	✓	10.5 V	✓	-			
TCK321G	WCSP16C	2.3 to 36	2	98 @4.5 V, -1 A	170 @4.5 V, -1 A	✓	✓	✓	V _{INA} = V _{VINB} = 12 V	✓	Pull down	V _{INA}	Dual input Single output	
TCK322G						✓	✓	✓	V _{INA} = V _{VINB} = 15 V	✓		V _{INA}		
TCK323G						✓	✓	✓	V _{INA} = V _{VINB} = 15 V	✓		V _{VINB}		

■ eFuse ICs

WSON10B	WSON10	WSON8
Bottom View 	Bottom View 	Bottom View 
3.0 x 3.0	3.0 x 3.0	2.0 x 2.0

Part Number	Package	Operating voltage range (V)	Output current (A)	R _{DS(on)} typ. (mΩ) @Ta = 25 °C	R _{DS(on)} max (mΩ) @Ta = -40 to 85 °C	Function							Note	
						Inrush current reduction	Thermal shutdown	Over voltage Clamp	Auto discharge	Under voltage lockout	Reverse current blocking	Fault Response		Over current protection
TCKE712BNL ☆	WSON10	4.4 to 13.2	3.65	53 @12 V, -1 A	80 @12 V, -1 A	Slew rate control by External Capacitance	✓	Adjustable		✓	✓	Latched	Adjustable	FLAG Indicates
TCKE805NA	WSON10B	4.4 to 18	5	28 @5 V, -1.5 A	38 @5 V, -1.5 A		✓	6.04 V typ.	✓	✓	*	Auto-retry	Adjustable	FLAG Indicates
TCKE805NL							✓	6.04 V typ.	✓	✓	*	Latched	Adjustable	
TCKE812NA							✓	15.1 V typ.	✓	✓	*	Auto-retry	Adjustable	
TCKE812NL							✓	15.1 V typ.	✓	✓	*	Latched	Adjustable	
TCKE800NA							✓	None	✓	✓	*	Auto-retry	Adjustable	
TCKE800NL						✓	None	✓	✓	*	Latched	Adjustable		
TCKE903NA ★	WSON8	2.7 to 23	4	34 @5 V, -1.5 A	52 @5 V, -1.5 A Ta = -40 to 125 °C	Slew rate control by External Capacitance	✓	3.87 V typ.	✓	✓		Auto-retry	Adjustable	FLAG Indicates
TCKE903NL ★							✓	3.87 V typ.	✓	✓		Latched	Adjustable	
TCKE905ANA ★							✓	5.7 V typ.	✓	✓		Auto-retry	Adjustable	
TCKE905NL ★							✓	5.7 V typ.	✓	✓		Latched	Adjustable	
TCKE912NA ★							✓	13.7 V typ.	✓	✓		Auto-retry	Adjustable	
TCKE912NL ★							✓	13.7 V typ.	✓	✓		Latched	Adjustable	
TCKE920NA ★							✓	22.2 V typ.	✓	✓		Auto-retry	Adjustable	
TCKE920NL ★							✓	22.2 V typ.	✓	✓		Latched	Adjustable	
TCKE903QNA ★							✓	3.87 V typ.	✓ (Quick Discharge)	✓		Auto-retry	Adjustable	
TCKE905QNA ★							✓	5.7 V typ.	✓ (Quick Discharge)	✓		Auto-retry	Adjustable	

☆ New Products

★ Under development (The specification is subject to change without notice.)

* This function is supported when N-ch MOSFET is attached to the external terminal.

5. Linear ICs

Thermoflagger™ (Over Temperature Detection IC)

Package Dimensions (unit: mm)










	TCTH011AE ☆ Push-pull	TCTH012AE ☆ Push-pull	TCTH021AE ☆ Push-pull	TCTH022AE ☆ Push-pull	TCTH011BE ☆ Open-drain	TCTH012BE ☆ Open-drain	TCTH021BE ☆ Open-drain	TCTH022BE ☆ Open-drain
Package	ESV	ESV	ESV	ESV	ESV	ESV	ESV	ESV
Supply Voltage	1.7 to 5.5 V	1.7 to 5.5 V	1.7 to 5.5 V	1.7 to 5.5 V	1.7 to 5.5 V	1.7 to 5.5 V	1.7 to 5.5 V	1.7 to 5.5 V
Operation Temperature	-40 to 125 °C	-40 to 125 °C	-40 to 125 °C	-40 to 125 °C	-40 to 125 °C	-40 to 125 °C	-40 to 125 °C	-40 to 125 °C
PTCO output current (typ.)	1 μA	1 μA	10 μA	10 μA	1 μA	1 μA	10 μA	10 μA
FLAG signal latch function	-	included	-	included	-	included	-	included
Current Consumption (max)	2.6 μA	2.6 μA	16.5 μA	16.5 μA	2.6 μA	2.6 μA	16.5 μA	16.5 μA
High level output voltage @I _{PTCO} = -4 mA	3.03 V (min) @V _{DD} = 3.3 V	3.03 V (min) @V _{DD} = 3.3 V	3.03 V (min) @V _{DD} = 3.3 V	3.03 V (min) @V _{DD} = 3.3 V	-	-	-	-
Low level output voltage @I _{PTCO} = 4 mA	0.2 V (max) @V _{DD} = 3.3 V	0.2 V (max) @V _{DD} = 3.3 V	0.2 V (max) @V _{DD} = 3.3 V	0.2 V (max) @V _{DD} = 3.3 V	0.2 V (max) @V _{DD} = 3.3 V	0.2 V (max) @V _{DD} = 3.3 V	0.2 V (max) @V _{DD} = 3.3 V	0.2 V (max) @V _{DD} = 3.3 V

☆ New Products

“Thermoflagger™” is a trademark of Toshiba Electronic Devices & Storage Corporation.

Operational Amplifiers, Comparators

Package Dimensions (unit: mm)

MP6C	ESV (SOT-553)	USV (SOT-353)	UFV (SOT-353F)	SMV (SOT-25)	US8 (SOT-765)	SM8 (SOT-505)
Bottom View 						
1.45 x 1.0	1.6 x 1.6	2.0 x 2.1	2.0 x 2.1	2.9 x 2.8	2.0 x 3.1	2.9 x 4.0

Operational Amplifiers

Package	Type	Bipolar	
		Standard	Low Noise Wide Band
Single	SMV	TA75S01F	TA75S558F
Dual	SM8	TA75W01FU	TA75W558FU
V _{CC} , V _{EE} / V _{DD} , V _{SS}		±6 or 12 V	±18 V
Test condition		V _{CC} = 5 V V _{EE} = GND	V _{CC} = 15 V V _{EE} = -15 V
I _{CC} / I _{DD} (max)		0.8 mA @Single 1.2 mA @Dual	4 mA @Single 6 mA @Dual
V _{IO} (max)		7 mV	6 mV
I _{sink} (typ.)		20 mA	40 mA
I _{source} (typ.)		40 mA	40 mA
G _v (typ.)		100 dB	100 dB
V _{NI} (typ.)			2.5 μVrms
SR (typ.)			1 V / μs
f _r (typ.)		0.3 MHz	3 MHz

Package	Type	CMOS						
		Low Voltage Operation	Standard	Low I _{DD}	Low I _{DD} I/O Full range	Ultra Low I _{DD} I/O Full range	Low Noise	Ultra Low Noise
Single	ESV				TC75S103FE ★	TC75S102FE ★		
	USV	TC75S51FU	TC75S54FU	TC75S55FU				
	UFV				TC75S103TU ★	TC75S102TU ★	TC75S63TU	TC75S67TU
	SMV	TC75S51F	TC75S54F	TC75S55F	TC75S103F ☆	TC75S102F ☆		
Dual	US8	TC75W51FK	TC75W54FK	TC75W55FK				
	SM8	TC75W51FU	TC75W54FU	TC75W55FU				
V _{CC} , V _{EE} / V _{DD} , V _{SS}		7 V	7 V	7 V	6 V	6 V	6 V	6 V
Test condition		V _{DD} = 3 V	V _{DD} = 3 V	V _{DD} = 3 V	V _{DD} = 3.3 V	V _{DD} = 1.5 V	V _{DD} = 3.3 V	V _{DD} = 3.3 V
I _{CC} / I _{DD} (max)		200 μA @Single 400 μA @Dual	200 μA @Single 400 μA @Dual	20 μA @Single 40 μA @Dual	165 μA	0.46 μA	650 μA	700 μA
V _{IO} (max)		10 mV	10 mV	10 mV	1.85 mV	1.3 mV	7 mV	3 mV
I _{sink} (typ.)			700 μA	450 μA	10 mA	0.4 mA	1.5 mA (min)	3.5 mA
I _{source} (typ.)			200 μA	20 μA	10 mA	0.6 mA	1.5 mA (min)	2.5 mA
G _v (typ.)		70 dB	70 dB	70 dB	125 dB	139 dB	100 dB	100 dB
V _{NI} (typ.)							7.8 nV / √Hz	6 nV / √Hz
SR (typ.)		0.5 V / μs	0.7 V / μs	0.08 V / μs	0.4 V / μs	0.37 V / ms	1 V / μs	1 V / μs
f _r (typ.)		0.6 MHz	0.9 MHz	0.16 MHz	0.36 MHz	0.5 kHz	3.5 MHz	3.5 MHz

Comparators



Package	Type	Bipolar	CMOS				
		Standard	Push pull		Open drain		
			Full-range input/output	Low I _{DD}	High speed	Low I _{DD}	High speed
Single	MP6C		TC75S70L6X				
	USV			TC75S56FU	TC75S57FU	TC75S58FU	TC75S59FU
	SMV	TA75S393F		TC75S56F	TC75S57F	TC75S58F	TC75S59F
Dual	US8			TC75W56FK	TC75W57FK	TC75W58FK	TC75W59FK
	SM8	TA75W393FU		TC75W56FU	TC75W57FU	TC75W58FU	TC75W59FU
V _{CC} , V _{EE} / V _{DD} , V _{SS}		±18 or 36 V	±3 or 6 V	±3.5 or 7 V	±3.5 or 7 V	±3.5 or 7 V	±3.5 or 7 V
Test condition		V _{CC} = 5 V	V _{DD} = 3 V	V _{DD} = 5 V	V _{DD} = 5 V	V _{DD} = 5 V	V _{DD} = 5 V
I _{CC} / I _{DD} (max)		0.8 mA @Single 2 mA @Dual	35 μA	22 μA @Single 44 μA @Dual	220 μA @Single 440 μA @Dual	22 μA @Single 44 μA @Dual	220 μA @Single 440 μA @Dual
I _{sink} (typ.)		16 mA	18 mA	25 mA	25 mA	25 mA	25 mA
I _{source} (typ.)			15 mA	21 mA	21 mA	21 mA	21 mA
G _v (typ.)		200 V / mV		94 dB	94 dB	94 dB	94 dB
t _{rsp} , t _{PLH} (typ.)		1.3 μs	400 ns	680 ns	140 ns	400 ns	200 ns

★ New Products, ★ Under Development (The specification is subject to change without notice.)

6. Sensors

Magnetic Sensors

Package Dimensions (unit: mm)

UFV (SOT-353F)	SOT-23F
 2.0 x 2.1	 2.9 x 2.4

		TCS40DPR	TCS40DLR	TCS30DPU	TCS30DLU	TCS30SPU	TCS30NPU
		Push pull	Open drain	Push pull	Open drain	Push pull	
Package		SOT-23F		UFV			
Detective Polarity		S&N		S&N	S	N	
Electrical Characteristics	Supply Voltage	2.3 to 5.5 V		2.3 to 3.6 V			
	Magnetic Flux Density	Operating Point ($V_{CC} = 2.3$ to 3.6 V)	$B_{ON} = 3.4$ mT (typ.)		$B_{ON} = 1.8$ mT (typ.)		
		Releasing Point ($V_{CC} = 2.3$ to 3.6 V)	$B_{OFF} = 2$ mT (typ.)		$B_{OFF} = 0.8$ mT (typ.)		
		Hysteresis ($V_{CC} = 2.3$ to 5 V)	$B_H = 1.4$ mT (typ.)		$B_H = 1$ mT (typ.)		
	Supply Current *	Average Current ($V_{CC} = 2.3$ V)	7.3 μ A (typ.)		8.5 μ A (typ.)		
	Operating Frequency ($V_{CC} = 2.3$ to 5 V)	25 Hz (typ.)		25 Hz (typ.)			

* Supply current is pulsed periodically by internal circuit.

7. General Purpose Logic ICs

7-1 One-Gate Logic ICs (L-MOS)

Package Dimensions (unit: mm)

VHS Series

General Specification	
Supply voltage range	: 2 to 5.5 V
Output current	: ± 8 mA (@ $V_{CC} = 4.5$ V)
Propagation delay time	: 3.7 nsec typ. (@ $V_{CC} = 5$ V)
Quiescent supply current	: 2 μ A max (@ $V_{CC} = 5.5$ V, $T_a = 25$ °C)
Operating temperature	: $T_{opr} = -40$ to 125 °C








USV (SOT-353)	SMV (SOT-25)	US8 (SOT-765)	SM8 (SOT-505)
			
2.0 x 2.1	2.9 x 2.8	2.0 x 3.1	2.9 x 4.0

Function		Part Number						
		USV		SMV		US8	SM8	
		-	TTL Input	-	TTL Input			
Gate / Buffer	NAND	TC7SH00FU #	TC7SET00FU #	TC7SH00F #	TC7SET00F #	TC7WH00FK # Dual-gate	TC7WH00FU Dual-gate	
	AND		TC7SH08FU #	TC7SET08FU #	TC7SH08F #	TC7SET08F #	TC7WH08FK # Dual-gate	TC7WH08FU Dual-gate
		Open-drain	TC7SH09FU #		TC7SH09F #			
	NOR	TC7SH02FU #	TC7SET02FU #	TC7SH02F #	TC7SET02F #	TC7WH02FK # Dual-gate	TC7WH02FU Dual-gate	
	OR	TC7SH32FU #	TC7SET32FU #	TC7SH32F #	TC7SET32F #	TC7WH32FK # Dual-gate	TC7WH32FU Dual-gate	
	Exclusive-OR	TC7SH86FU #		TC7SH86F #				
	Inverter		TC7SH04FU #	TC7SET04FU #	TC7SH04F #	TC7SET04F #	TC7WH04FK # Triple-gate	TC7WH04FU Triple-gate
		Unbuffered	TC7SHU04FU #		TC7SHU04F #		TC7WHU04FK # Triple-gate	TC7WHU04FU Triple-gate
		Schmitt	TC7SH14FU #	TC7SET14FU #	TC7SH14F #	TC7SET14F #	TC7WH14FK # Triple-gate	TC7WH14FU Triple-gate
	Buffer	Schmitt	TC7SH17FU #	TC7SET17FU #	TC7SH17F #	TC7SET17F #	TC7WH17FK # Triple-gate	TC7WH17FU Triple-gate
	Non-Inverter		TC7SH34FU #	TC7SET34FU #	TC7SH34F #	TC7SET34F #	TC7WH34FK # Triple-gate	TC7WH34FU Triple-gate
	3-state	Buffer	TC7SH125FU #	TC7SET125FU #	TC7SH125F #	TC7SET125F #	TC7WH125FK # Dual-gate	TC7WH125FU Dual-gate
			TC7SH126FU #	TC7SET126FU #	TC7SH126F #	TC7SET126F #	TC7WH126FK # Dual-gate	TC7WH126FU Dual-gate
D-Type Flip-Flop	Preset and Clear					TC7WH74FK #	TC7WH74FU	
Multiplexers	Digital					TC7WH157FK #	TC7WH157FU	

This device is compliant with the reliability requirements of AEC-Q100

SHS Series

General Specification	
Supply voltage range	: 1.65 to 5.5 V
Output current	: ± 24 mA (@ $V_{CC} = 3$ V)
Propagation delay time	: 2.4 nsec typ. (@ $V_{CC} = 3.3$ V)
Quiescent supply current	: 1 μ A max (@ $V_{CC} = 5.5$ V, $T_a = 25$ °C)
Operating temperature	: $T_{opr} = -40$ to 125 °C


fsv (SOT-953)	ESV (SOT-553)	USV (SOT-353)	SMV (SOT-25)	US6 (SOT-363)	US8 (SOT-765)	SM8 (SOT-505)
						
1.0 x 1.0	1.6 x 1.6	2.0 x 2.1	2.9 x 2.8	2.0 x 2.1	2.0 x 3.1	2.9 x 4.0

Function		Part Number							
Package	fsv	ESV	USV	SMV	US6	US8	SM8		
Gate / Buffer	NAND	TC7SZ00AFS	TC7SZ00FE #	TC7SZ00FU #	TC7SZ00F #		TC7WZ00FK # Dual-gate	TC7WZ00FU Dual-gate	
	AND	TC7SZ08AFS	TC7SZ08FE #	TC7SZ08FU #	TC7SZ08F #		TC7WZ08FK # Dual-gate	TC7WZ08FU Dual-gate	
	NOR	TC7SZ02AFS	TC7SZ02FE #	TC7SZ02FU #	TC7SZ02F #		TC7WZ02FK # Dual-gate	TC7WZ02FU Dual-gate	
	OR	TC7SZ32AFS	TC7SZ32FE #	TC7SZ32FU #	TC7SZ32F #		TC7WZ32FK # Dual-gate	TC7WZ32FU Dual-gate	
	Exclusive-OR	TC7SZ86AFS	TC7SZ86FE #	TC7SZ86FU #	TC7SZ86F #		TC7WZ86FK # Dual-gate	TC7WZ86FU Dual-gate	
	Inverter		TC7SZ04AFS	TC7SZ04FE #	TC7SZ04FU #	TC7SZ04F #	TC7PZ04FU # Dual-gate	TC7WZ04FK # Triple-gate	TC7WZ04FU Triple-gate
		Unbuffered	TC7SZU04AFS	TC7SZU04FE #	TC7SZU04FU #	TC7SZU04F #		TC7WZU04FK # Triple-gate	TC7WZU04FU Triple-gate
		Open-drain	TC7SZ05AFS	TC7SZ05FE #	TC7SZ05FU #	TC7SZ05F #	TC7PZ05FU # Dual-gate	TC7WZ05FK # Triple-gate	TC7WZ05FU Triple-gate
	Schmitt		TC7SZ14AFS	TC7SZ14FE #	TC7SZ14FU #	TC7SZ14F #	TC7PZ14FU # Dual-gate	TC7WZ14FK # Triple-gate	TC7WZ14FU Triple-gate
		Open-drain	TC7SZ07AFS	TC7SZ07FE #	TC7SZ07FU #	TC7SZ07F #	TC7PZ07FU # Dual-gate	TC7WZ07FK # Triple-gate	TC7WZ07FU Triple-gate
	Schmitt		TC7SZ17AFS	TC7SZ17FE #	TC7SZ17FU #	TC7SZ17F #	TC7PZ17FU # Dual-gate	TC7WZ17FK # Triple-gate	TC7WZ17FU Triple-gate
		Open-drain	TC7SZ07AFS	TC7SZ07FE #	TC7SZ07FU #	TC7SZ07F #	TC7PZ07FU # Dual-gate	TC7WZ07FK # Triple-gate	TC7WZ07FU Triple-gate
	Non-Inverter		TC7SZ34AFS	TC7SZ34FE #	TC7SZ34FU #	TC7SZ34F #	TC7PZ34FU # Dual-gate	TC7WZ34FK # Triple-gate	TC7WZ34FU Triple-gate
	3-state Buffer		TC7SZ125AFS	TC7SZ125FE #	TC7SZ125FU #	TC7SZ125F #		TC7WZ125FK # Dual-gate	TC7WZ125FU Dual-gate
		TC7SZ126AFS	TC7SZ126FE #	TC7SZ126FU #	TC7SZ126F #		TC7WZ126FK # Dual-gate	TC7WZ126FU Dual-gate	
D-Type Flip-Flop	Preset and Clear						TC7WZ74FK #	TC7WZ74FU	

This device is compliant with the reliability requirements of AEC-Q100

7UL1Gxx Series



General Specification	
Supply voltage range	: 0.9 to 3.6 V
Output current	: ± 8 mA (@ $V_{CC} = 3$ V)
Propagation delay time	: 2.5 nsec typ. (@ $V_{CC} = 3.3$ V)
Quiescent supply current	: 1 μ A max (@ $V_{CC} = 3.6$ V, $T_a = 25$ °C)
Operating temperature	: $T_{opr} = -40$ to 125 °C

fSV (SOT-953)	USV (SOT-353)	US8 (SOT-765)	XSON6 (MP6D)
			
1.0 x 1.0	2.0 x 2.1	2.0 x 3.1	Bottom View 1.45 x 1.0

Function		Part Number				
Package		fSV	USV	US8	XSON6 (MP6D)	
Gate / Buffer	NAND Gate	7UL1G00FS	7UL1G00FU	7UL2G00FK	7UL1G00NX ★	
	NOR Gate	7UL1G02FS	7UL1G02FU	7UL2G02FK	7UL1G02NX ★	
	Inverter		7UL1G04FS	7UL1G04FU	7UL3G04FK	7UL1G04NX ☆
		Unbuffered	7UL1GU04FS	7UL1GU04FU	7UL3GU04FK	7UL1GU04NX ☆
	AND Gate	7UL1G08FS	7UL1G08FU	7UL2G08FK	7UL1G08NX ★	
	Schmitt Inverter	7UL1G14FS	7UL1G14FU	7UL3G14FK	7UL1G14NX ☆	
	Schmitt Buffer	7UL1G17FS	7UL1G17FU	7UL3G17FK	7UL1G17NX ☆	
	OR Gate	7UL1G32FS	7UL1G32FU	7UL2G32FK	7UL1G32NX ★	
	Buffer		7UL1G34FS	7UL1G34FU	7UL3G34FK	7UL1G34NX ☆
		Open drain		7UL1G07FU		
	Exclusive-OR	7UL1G86FS	7UL1G86FU	7UL2G86FK	7UL1G86NX ★	
	3-State Buffer(/G)	7UL1G125FS	7UL1G125FU	7UL2G125FK	7UL1G125NX ☆	
3-State Buffer(G)	7UL1G126FS	7UL1G126FU	7UL2G126FK	7UL1G126NX ★		

7UL1Txx Series

General Specification	
Supply voltage range	: 2.3 to 3.6 V
Output level up to supply V_{CC} CMOS level	: 1.65 to 3.6 V (@ $V_{CC} = 3.6$ V)
Output level down to supply V_{CC} CMOS level	: 3.6 to 2.3 V (@ $V_{CC} = 2.3$ V)
Quiescent supply current	: 1 μ A max (@ $V_{CC} = 3.6$ V, $T_a = 25$ °C)
Operating temperature	: $T_{opr} = -40$ to 125 °C

fSV (SOT-953)	USV (SOT-353)	US8 (SOT-765)	XSON6 (MP6D)
			
1.0 x 1.0	2.0 x 2.1	2.0 x 3.1	Bottom View 1.45 x 1.0

Function		Part Number			
Package		fSV	USV	US8	XSON6(MP6D)
Gate / Buffer	NAND Gate	7UL1T00FS	7UL1T00FU	7UL2T00FK	7UL1T00NX ★
	NOR Gate	7UL1T02FS	7UL1T02FU	7UL2T02FK	7UL1T02NX ★
	Inverter	7UL1T04FS	7UL1T04FU	7UL3T04FK	7UL1T04NX ★
	AND Gate	7UL1T08FS	7UL1T08FU	7UL2T08FK	7UL1T08NX ★
	OR Gate	7UL1T32FS	7UL1T32FU	7UL2T32FK	7UL1T32NX ★
	Buffer	7UL1T34FS	7UL1T34FU	7UL3T34FK	7UL1T34NX ★
	Exclusive-OR	7UL1T86FS	7UL1T86FU	7UL2T86FK	7UL1T86NX ★
	3-State Buffer(/G)	7UL1T125FS	7UL1T125FU	7UL2T125FK	7UL1T125NX ★
	3-State Buffer(G)	7UL1T126FS	7UL1T126FU	7UL2T126FK	7UL1T126NX ★

☆ New Products

★ Under Development (The specification is subject to change without notice.)

7-2 CMOS Logic ICs

Standard Logic 74VHC Series (TSSOP14B / 16B / 20B Package Products)

Package Dimensions (unit: mm)

TSSOP14B	TSSOP16B	TSSOP20B
		
5.0 x 6.4	5.0 x 6.4	6.5 x 6.4




Features
• Compliant with the reliability requirements of AEC-Q100 Operating temperature: Available -40 to 125 °C products
• Compatible standard TSSOP package

Series name			VHC	VHCT (TTL Input)	VHCV (Schmitt Input)	VHC9 (Schmitt Input)		
Characteristics and Features	Supply voltage range		2 to 5.5 V	4.5 to 5.5 V	1.8 to 5.5 V	2 to 5.5 V 4.5 to 5.5 V (VHCT9)		
	Output current @V _{CC} = 4.5 V		±8 mA		±16 mA	±8 mA		
	Power down protection on inputs		Yes					
	Power down protection on outputs		No	Yes				
Function			Pin					
Gate / Buffer	NAND	Quad	14	74VHC00FT #	74VHCT00AFT #			
		Open-drain	14	74VHC03FT #				
		Schmitt	14	74VHC132FT #				
	AND	Dual	4-input	14	74VHC20FT #			
		Quad		14	74VHC08FT #	74VHCT08AFT #		
	NOR	Dual	4-input	14	74VHC21FT #			
		Quad		14	74VHC02FT #			
	OR	Dual	4-input	14	74VHC27FT #			
		Quad		14	74VHC32FT #	74VHCT32AFT #		
	Exclusive-OR	Quad		14	74VHC86FT #			
		Inverter	Hex	14	74VHC04FT #	74VHCT04AFT #		
	Open-drain		14	74VHC05FT #		74VHCV05FT #		
	Schmitt		14	74VHC14FT #	74VHCT14AFT #	74VHCV14FT #		
	Buffer	9-bit		20			74VHC9152FT #	
		Hex		14			74VHCV17FT #	
			Open-drain	14			74VHCV07FT #	
		Dual 3-bit	Pull-down resistor	20				74VHC9363FT
	Pull-up resistor		20				74VHC9364FT	
			20				74VHC9151FT #	
	3-state Buffer	Quad		14	74VHC125FT #	74VHCT125AFT #		
				14	74VHC126FT #	74VHCT126AFT #		
		5-Bit Universal Schmitt Buffer		14				74VHC9125FT #
								74VHCT9125AFT #
								74VHC9126FT #
		Octal	Inverted		20	74VHC240FT #	74VHCT240AFT #	74VHCV240FT #
					20	74VHC540FT #	74VHCT540AFT #	74VHCV540FT #
	Universal Schmitt Buffer			20	74VHC244FT #	74VHCT244AFT #	74VHCV244FT #	
				20	74VHC541FT #	74VHCT541AFT #	74VHCV541FT #	
Transceiver	Octal		20	74VHC245FT #	74VHCT245AFT #	74VHCV245FT #		
	Dual		14	74VHC74FT #				
Flip-Flop	Hex		16	74VHC174FT #				
			20	74VHC273FT #		74VHC9273FT #		
	3-state	Octal		20	74VHC374FT #		74VHCT9273FT #	
				20	74VHC574FT #	74VHCT574AFT #	74VHCV574FT #	
Latch	3-state	Octal	20	74VHC373FT #	74VHCT373AFT #	74VHCV373FT #		
			20	74VHC573FT #	74VHCT573AFT #	74VHCV573FT #		
			16	74VHC123AFT #				
Multi-vibrator	Dual		16	74VHC221AFT #				
			16	74VHC138FT #	74VHCT138AFT #			
Decoder	3 to 8 line	Single	16	74VHC238FT #				
			16	74VHC139FT #				
Shift Register	8bit	S-in / P-out	14	74VHC164FT #				
			S-in / P-out, P-in / S-out	16			74VHC9164FT #	
		P-in / S-out		16	74VHC165FT #			
			3-state	16	74VHC595FT #		74VHC9595FT #	
Counter	Binary	Single 4bit with	16	74VHC161FT #				
			16	74VHC163FT #				
		Dual	4bit	14	74VHC393FT #			
			14-stage	16	74VHC4020FT #			
		12-stage	16	74VHC4040FT #				
Multiplexer	Digital	Dual-4ch.	16	74VHC153FT #				
		Quad-2ch.	16	74VHC157FT #				
	Analog	Single-8ch.	16	74VHC4051AFT #				
		Dual-4ch.	16	74VHC4052AFT #				
		Triple-2ch.	16	74VHC4053AFT #				
Other	Analog switch	Quad	14	74VHC4066AFT #				

This device is compliant with the reliability requirements of AEC-Q100

■ Standard Logic 74HC Series, 74LCX Series (TSSOP14B / 16B / 20B Package Products)

Package Dimensions (unit: mm)




TSSOP14B	TSSOP16B	TSSOP20B	Features
			74LCX Series • Compliant with the reliability requirements of AEC-Q100 Operating temperature: Available -40 to 125 °C products (‡ Operation temperature of this device is -40 to 85 °C.) • Compatible standard TSSOP package 74HC/HCT Series • Available -40 to 125 °C products, Compatible standard TSSOP package
5.0 x 6.4	5.0 x 6.4	6.5 x 6.4	

Series name			HC	HCT (TTL Input)	LCX	
Characteristics and Features	Supply voltage range		2 to 6 V	4.5 to 5.5 V	1.65 to 3.6 V to 5.5 V (05 and 07)	
	Output current @V _{CC} = 4.5 V		±4 or ±6 mA		±24 mA (@V _{CC} = 3 V)	
	Power down protection on inputs		No		Yes	
	Power down protection on outputs		No		Yes	
Function			Pin			
Gate / Buffer	NAND	Quad	14		74LCX00FT #	
	AND	Quad	14		74LCX08FT #	
	NOR	Quad	14		74LCX02FT #	
	OR	Quad	14		74LCX32FT #	
	Exclusive-OR	Quad	14		74LCX86FT #	
	Inverter	Hex		14		74LCX04FT #
				16	TC74HC4049AFT &	
			Unbuffer	14	TC74HCU04AFT &	
			Open-drain	14		74LCX05FT #
			Schmitt	14		74LCX14FT #
	Buffer	Hex		16	TC74HC4050AFT &	
			Open-drain	14		74LCX07FT #
				14		74LCX125FT #
	3-state Buffer	Quad		14		74LCX126FT #
				14		74LCX126FT #
		Octal	Inverted		20	
				20		74LCX540FT # ‡
				20		74LCX244FT # ‡
				20		74LCX541FT # ‡
Transceiver	Octal	20		74LCX245FT # ‡		
Flip-Flop	Dual		14		74LCX74FT #	
			20		74LCX273FT #	
	3-state	Octal		20		74LCX374FT # ‡
				20		74LCX574FT # ‡
Latch	3-state	Octal	20		74LCX373FT # ‡	
			20		74LCX573FT # ‡	
Multivibrator	Dual	Retriggerable / Resettable	16	74HC4538FT		
Decoder	3 to 8 line	Single	16		74LCX138FT #	
Multiplexer	Digital	Quad-2ch.	16		74LCX157FT #	
			3-state	16		74LCX257FT #
	Analog	Single-8ch.		16	74HC4051FT	74HCT4051FT
				16	74HC4052FT	74HCT4052FT
Other	Analog switch	Quad	16	74HC4053FT	74HCT4053FT	
			14	74HC4066FT		

This device is compliant with the reliability requirements of AEC-Q100
 ‡ Operation temperature is -40 to 85 °C
 & The package for this product is TSSOP14 / 16.

Standard Logic 74VHC Series (US14 / 16 / 20 Package Products)

Package Dimensions (unit: mm)

US14	US16	US20
		
4.0 x 4.0	4.0 x 4.0	5.0 x 4.0

Features
• Small mounting area and thin package

Series name		VHC		VHCT (TTL Input)		VHCV (Schmitt Input)		VHC9 (Schmitt Input)				
Characteristics and Features		Supply voltage range		2 to 5.5 V		4.5 to 5.5 V		1.8 to 5.5 V				
		Output current @V _{CC} = 4.5 V		±8 mA		±16 mA		±8 mA				
		Power down protection on inputs				Yes						
		Power down protection on outputs		No				Yes				
Function		Pin										
Gate / Buffer	NAND	Quad	14	TC74VHC00FK	TC74VHCT00AFK							
			Open-drain Schmitt	14	TC74VHC03FK							
		Dual	4-input	14	TC74VHC20FK							
			4-input	14	TC74VHC08FK	TC74VHCT08AFK						
	AND	Quad	14	TC74VHC21FK								
		Dual	4-input	14	TC74VHC02FK							
	NOR	Quad	14	TC74VHC27FK								
		Dual	4-input	14	TC74VHC32FK	TC74VHCT32AFK						
	OR	Quad	14	TC74VHC86FK								
		Quad	14	TC74VHC04FK	TC74VHCT04AFK							
	Exclusive-OR	Hex	Open-drain Schmitt	14	TC74VHC05FK			TC74VHCV05FK				
				14	TC74VHC14FK	TC74VHCT14AFK		TC74VHCV14FK				
			9-bit	20				TC74VHCV17FK		TC74VHC9152FK		
	Buffer	Hex	Open-drain	14				TC74VHCV07FK				
				9-bit	20						TC74VHC9151FK	
	3-state Buffer	Quad		14	TC74VHC125FK	TC74VHCT125AFK						
				14	TC74VHC126FK	TC74VHCT126AFK						
		5-Bit Universal Schmitt Buffer			14				TC74VHC9125FK		TC74VHC9125AFK	
					14				TC74VHC9126FK		TC74VHC9126AFK	
					20	TC74VHC240FK	TC74VHCT240AFK		TC74VHCV240FK			
20					TC74VHC540FK	TC74VHCT540AFK		TC74VHCV540FK				
Octal	Inverted		20	TC74VHC244FK	TC74VHCT244AFK		TC74VHCV244FK					
			20	TC74VHC541FK	TC74VHCT541AFK		TC74VHCV541FK					
			20						TC74VHC9541FK			
			20	Universal Schmitt Buffer					TC74VHCT9541AFK			
Transceiver	Octal		20	TC74VHC245FK	TC74VHCT245AFK		TC74VHCV245FK					
			14	TC74VHC74FK								
			16	TC74VHC174FK								
			20	TC74VHC273FK					TC74VHC9273FK			
3-state	Octal		20	TC74VHC374FK			TC74VHCV374FK					
			20	TC74VHC574FK	TC74VHCT574AFK		TC74VHCV574FK					
Latch	3-state	Octal	20	TC74VHC373FK			TC74VHCV373FK					
			20	TC74VHC573FK	TC74VHCT573AFK		TC74VHCV573FK					
			16	TC74VHC123AFK								
Multi-vibrator	Dual		16	TC74VHC221AFK								
			16	TC74VHC138FK	TC74VHCT138AFK							
Decoder	3 to 8 line	Single	16	TC74VHC238FK								
			16	TC74VHC139FK								
			14	TC74VHC164FK								
Shift Register	8bit	S-in / P-out	16	TC74VHC165FK					TC74VHC9164FK			
			16	TC74VHC595FK					TC74VHC9595FK			
			16	TC74VHC161FK								
			16	TC74VHC163FK								
Counter	Binary	Single 4bit with Async. Clear	16	TC74VHC393FK								
			16	TC74VHC4020FK								
		Dual 4bit	14-stage	16	TC74VHC4040FK							
				16	TC74VHC153FK							
Multiplexer	Digital	Quad-2ch.	16	TC74VHC157FK								
			16	TC74VHC4051AFK								
	Analog	Single-8ch.	Dual-4ch.	16	TC74VHC4052AFK							
				16	TC74VHC4053AFK							
Other	Analog switch	Quad	14	TC74VHC4066AFK								

1 MOSFETS

2 Tr./BJT's

3 Diodes

4 Power Management IC's

5 Linear IC's

6 Sensors




7 General Purpose Logic IC's

8 RF Devices

9 Packages







■ Standard Logic 74LCX Series, 74VCX Series (US14 / 16 / 20 Package Products)

Package Dimensions (unit: mm)

US14				US16				US20				Features			
												• Small mounting area and thin package			
4.0 x 4.0				4.0 x 4.0				5.0 x 4.0							
Series name				LCX				VCX							
Characteristics and Features				Supply voltage range				1.65 to 3.6 V to 5.5 V (05 and 07)				1.2 to 3.6 V			
				Output current @V _{CC} = 3 V				±24 mA				±24 mA			
				Power down protection on inputs				Yes				Yes			
				Power down protection on outputs				Yes				Yes			
Function				Pin				Function				Pin			
Gate / Buffer	NAND	Quad	14	TC74LCX00FK				TC74VCX00FK							
	AND	Quad	14	TC74LCX08FK				TC74VCX08FK							
	NOR	Quad	14	TC74LCX02FK				TC74VCX02FK							
	OR	Quad	14	TC74LCX32FK				TC74VCX32FK							
	Exclusive-OR	Quad	14	TC74LCX86FK											
	Inverter	Hex		14	TC74LCX04FK				TC74VCX04FK						
			Open-drain	14	TC74LCX05FK										
			Schmitt	14	TC74LCX14FK				TC74VCX14FK						
	Buffer	Hex	Open-drain	14	TC74LCX07FK										
	3-state Buffer	Quad		14	TC74LCX125FK				TC74VCX125FK						
				14	TC74LCX126FK										
		Octal	Series resistor		14					TC74VCX2125FK					
				Inverted	20	TC74LCX240FK									
				20	TC74LCX540FK										
				20	TC74LCX244FK				TC74VCX244FK						
	Series resistor		20	TC74LCX541FK				TC74VCX541FK							
		20					TC74VCX2244FK								
			20					TC74VCX2541FK							
Transceiver	Octal	20	TC74LCX245FK				TC74VCX245FK								
Flip-Flop		Dual	14	TC74LCX74FK											
		Octal	20	TC74LCX273FK											
	3-state	Octal	20	TC74LCX374FK											
			20	TC74LCX574FK				TC74VCX574FK							
Latch	3-state	Octal	20	TC74LCX373FK											
			20	TC74LCX573FK											
Decoder	3 to 8 line	Single	16	TC74LCX138FK				TC74VCX138FK							
Multi-plexer	Digital	Quad-2ch.	16	TC74LCX157FK				TC74VCX157FK							
			3-state	16	TC74LCX257FK				TC74VCX257FK						

Standard Logic 74HC Series, TC4000B Series (SOIC14 / 16 / 20, SOP14 / 16 / 20 Package Products)

Package Dimensions (unit: mm)

SOIC14	SOIC16	SOIC20	SOP14	SOP16	SOP20
					
8.65 x 6.0	9.9 x 6.0	12.8 x 10.3	10.3 x 7.8	10.3 x 7.8	12.8 x 7.8

Series name			SOIC Package		SOP Package				
			HC	HCT (TTL Input)	HC	HCT (TTL Input)	Standard series		
Characteristics and Features	Supply voltage range		2 to 6 V	4.5 to 5.5 V	2 to 6 V	4.5 to 5.5 V	3 to 18 V		
	Output current @V _{cc} = 4.5 V		±4 or ±6 mA	±4 or ±6 mA	±4 or ±6 mA	±4 or ±6 mA	±0.51 mA (@V _{cc} = 5 V)		
	Power down protection on inputs		No		No		No		
	Power down protection on outputs		No		No		No		
Function			Pin						
Gate / Buffer	NAND	Quad	14	74HC00D †		TC74HC00AF		TC4011BF	
			14	74HC03D †					
		Open-drain Schmitt 4-input	14			TC74HC132AF		TC4093BF	
			14			TC74HC20AF			
	AND	Quad	14	74HC08D †		TC74HC08AF		TC4081BF	
			14			TC74HC21AF			
	NOR	Quad	14			TC74HC02AF		TC4001BF	
			14	74HC32D †		TC74HC32AF		TC4071BF	
	OR	Quad	14	74HC86D †				TC4030BF	
			14	74HC04D †		TC74HC04AF	TC74HCT04AF	TC4069UBF	
	Exclusive-OR Inverter	Hex	Unbuffer	16			TC74HC4049AF		TC4049BF
				14			TC74HCU04AF		
			Open-drain Schmitt	14	74HC05D †		TC74HC05AF		
				14	74HC14D †	74HCT14D †	TC74HC14AF		TC4584BF
	Buffer	Hex	Open-drain	16			TC74HC4050AF		TC4050BF
				14			TC74HC07AF		
	3-state Buffer	Quad	Universal	14	74HC125D †		TC74HC125AF		
				14	74HC126D †		TC74HC126AF		
				14			TC74HC365AF		
				14			TC74HC366AF		
		Octal	Inverted	20			TC74HC240AF	TC74HCT240AF	
				20			TC74HC540AF	TC74HCT540AF	
				20			TC74HC7240AF		
				20			TC74HC241AF		
Transceiver	Octal	Inverted Non-inverted	20			TC74HC244AF	TC74HCT244AF		
			20			TC74HC541AF	TC74HCT541AF		
			20			TC74HC640AF			
			20	74HC245D †	74HCT245D †	TC74HC245AF			
Flip-Flop	Dual	Hex	14			TC74HC74AF		TC4013BF	
			16	74HC175D †		TC74HC175AF			
	3-state	Octal	Octal	20	74HC273D †		TC74HC273AF		
				20	74HC374D †		TC74HC374AF		
Latch	8-Bit Addressable Latch	3-state	16	74HC574D †		TC74HC574AF			
			20	74HC259D †					
Multi-vibrator	Dual Monostable	Retriggerable Retrienable/Resetable	16			TC74HC373AF			
			16	74HC538D †		TC74HC538AF		TC4538BF	
Decoder	3 to 8 line	Single	16			TC74HC42AF			
			16	74HC138D †		TC74HC138AF			
			16	74HC238D †					
			16	74HC237D †					
Shift Register	8bit	S-in / P-out P-in / S-out with Clear With Output Register Latch (3-state) 8-Stage Shift-and-Store	14	74HC164D †				TC4511BF	
			16			TC74HC165AF		TC4021BF	
			16	74HC166D †					
			16	74HC594D †		TC74HC595AF			
Counter	Binary	Single	16			TC74HC373AF		TC4094BF	
			16			TC74HC573AF		TC4020BF	
		14-stage 12-stage	16			TC74HC123AF		TC4040BF	
			16			TC74HC4020AF			
		Single 14-Stage / Oscillator Single Decade Counter/Divider Dual Binary Up Counter Programmable Divider / Timer	16			TC74HC4040AF		TC4040BF	
			16			TC74HC4060AF			
Multiplexer	Digital	Single-8ch. Single-8ch. 3-state Dual-4ch. Dual-4ch. 3-state Quad-2ch.	16	74HC151D †		TC74HC7292AF		TC4051BF	
			16			TC74HC151AF		TC4052BF	
			16			TC74HC251AF		TC4053BF	
			16			TC74HC153AF			
	Analog	Single-8ch. Dual-4ch. Triple-2ch.	Single-8ch. Dual-4ch. Triple-2ch.	16	74HC4051D †	74HCT4051D †	TC74HC4051AF	TC74HCT4051AF	TC4051BF
				16	74HC4052D †	74HCT4052D †	TC74HC4052AF	TC74HCT4052AF	TC4052BF
				16	74HC4053D †	74HCT4053D †	TC74HC4053AF	TC74HCT4053AF	TC4053BF
				16	74HC4066D †		TC74HC4066AF		TC4066BF
Other	Analog switch	Quad	14	74HC4066D †		TC74HC4066AF		TC4066BF	

† Operating temperature: T_{opr} = -40 to 125 °C

■ Standard Logic TC74VCX Series, TC74LCX Series (TSSOP14 / 16 / 20 / 48 Package Products)

Package Dimensions (unit: mm)



Series name				TSSOP Package		
				TC74VCX	TC74LCX	
Characteristics and Features		Supply voltage range	1.2 to 3.6 V			
		Output current @V _{CC} = 3 V	±24 mA			
		Power down protection on inputs	Yes			
		Power down protection on outputs	Yes			
		Function	Pin	-	-	
Gate / Buffer	NAND	Quad	14	TC74VCX00FT †		
		Quad	14	TC74VCX08FT †		
	AND	Quad	14	TC74VCX02FT †		
		Quad	14	TC74VCX32FT †		
	NOR	Quad	14	TC74VCX04FT †		
		Quad	14	TC74VCX14FT †		
	OR	Quad	14	TC74VCX125FT †		
		Quad	14	TC74VCX2125FT †		
	Inverter	Hex		14	TC74VCX244FT †	
			Schmitt	14	TC74VCX541FT †	
	3-state Buffer	Quad		14	TC74VCX2541FT †	
			Series resistor	14	TC74VCX2244FT †	
		Octal		20	TC74VCX2541FT †	
			Series resistor	20	TC74VCX2244FT †	
		16bit		20	TC74VCX2541FT †	
				48		TC74LCX16244 †
Transceiver	Octal		20	TC74VCX245FT †		
			48	TC74VCX16245 †	TC74LCX16245 †	
	16bit	Bus hold	48	TC74VCXH16245 †		
		Series resistor	48	TC74VCXR162245 †		
		Bus hold + Series resistor	48	T74VCXHR162245 †		
Flip-Flop	3-state	Octal	14	TC74VCX574FT †		
Decoder	3 to 8 line	Single	16	TC74VCX138FT †		
Multi-plexer	Digital	Quad-2ch.	16	TC74VCX157FT †		
		3-state	16	TC74VCX257FT †		

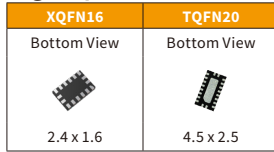
† Operating temperature: T_{opr} = -40 to 125 °C




7-3 Bus Switches

High-Speed Transmission Type

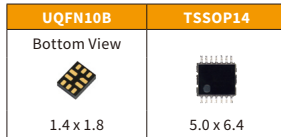
Package Dimensions (unit: mm)





High-Speed Transmission Type



Recommended application	Interface Speed	Part Number	Package	Number of lane	Specification			Pin Assignment	Switch function
					Supply Voltage Range	Band width @-3 dB (typ.)	Quiescent Supply Current (max)		
USB4® PCIe®-Gen4 Thunderbolt 4™ DP2.0™	to 20 Gbps	TDS4A212MX ☆	XQFN16	1 lane	1.6 to 3.6 V	26.2 GHz @V _{cc} = 1.6 to 3.6 V	150 μA @V _{cc} = 3.6 V		SPDT
		TDS4B212MX ☆				27.5 GHz @V _{cc} = 1.6 to 3.6 V			
USB3.1 PCIe®-Gen3	to 10 Gbps	TC7PCI3212MT	TQFN20	1 lane	3 to 3.6 V	11.5 GHz @V _{cc} = 3.3 V	500 μA @V _{cc} = 3.6 V		SPDT
		TC7PCI3215MT							

for USB2.0 and others



Recommended application	Interface Speed	Part Number	Package	Number of circuit	Specification			Pin Assignment	Switch function
					Supply Voltage Range	Band width @-3 dB (typ.)	Quiescent Supply Current (max)		
USB2.0 PCIe®-Gen1 HDMI™1.4 SATA2.0 SAS1.0	to 3.4 Gbps	TC7USB40MU	UQFN10B	2	2.3 to 4.3 V	1.5 GHz @V _{cc} = 3.3 V	1 μA @V _{cc} = 4.3 V		SPDT
		TC7USB42MU							
		TC7USB40FT	TSSOP14						
		TC7USB42FT							

☆ New Products

- USB4® USB4 is a registered trademark of USB Implementers Forum.
- PCIe® PCIe is a registered trademark of PCI-SIG.
- HDMI™ HDMI, HDMI High-Definition Multimedia Interface and the HDMI logo are trademarks or registered trademarks of HDMI Licensing LLC in the United States and other countries.
- Thunderbolt™ Thunderbolt is a trademark of Intel Corporation or its subsidiaries.
- DP™ DisplayPort, the DisplayPort logo, and the DisplayPort Certified Logo are trademarks or registered trademarks of the Video Electronics Standards Association in the United States and other countries

■ General Purpose Bus Switches

Package Dimensions (unit: mm)

USV (SOT-353)	XSON6 (MP6D)	US6 (SOT-363)	US8 (SOT-765)	US14	US16	US20	TSSOP14B	TSSOP16B	TSSOP20B
	Bottom View 								
2.0 x 2.1	1.45 x 1.0	2.0 x 2.1	2.0 x 3.1	4.0 x 4.0	4.0 x 4.0	5.0 x 4.0	5.0 x 6.4	5.0 x 6.4	6.5 x 6.4

5 V Bus Switch

Switch function	Part Number	Package	Number of circuit	Switch type	Specification			
					Supply Voltage Range	Switch I/O Capacitance @Switch OFF (typ.)	Switch ON Resistance @V _{cc} = 4.5 V, V _{is} = 0 V (typ.)	Quiescent Supply Current (max)
SPST	TC7SB66CFU # †	USV	1	P-ch + N-ch	1.65 to 5.5 V	5 pF @V _{cc} = 5 V	4 Ω @I _{is} = 30 mA	10 μA @V _{cc} = 5.5 V
	TC7SB67CFU # †							
	TC7WB66CFK # †	US8	2					
	TC7WB67CFK # †							
SPDT	TC7SB3157CFU # †	US6	1	P-ch + N-ch	1.65 to 5.5 V	5 pF @V _{cc} = 5 V	4 Ω @I _{is} = 30 mA	10 μA @V _{cc} = 5.5 V
	TC7SB3157DL6X	XSON6 (MP6D)						


Low-Voltage Bus Switch

Switch function	Part Number	Package	Number of circuit	Switch type	Specification			
					Supply Voltage Range	Switch I/O Capacitance	Switch ON Resistance @V _{cc} = 3 V, V _{is} = 0 V (typ.)	Quiescent Supply Current
SPST	TC7SBL66CFU # †	USV	1	P-ch + N-ch	1.65 to 3.6 V	3.5 pF @V _{cc} = 3 V	5.5 Ω @I _{is} = 30 mA	10 μA @V _{cc} = 3.6 V
	TC7SBL384CFU # †							
	TC7WBL3305CFK # †	US8	2				6 Ω @I _{is} = 30 mA	
	TC7WBL3306CFK # †							
	TC7MBL3125CFK	US14	4				6.5 Ω @I _{is} = 30 mA	
	TC7MBL3125CFT # †	TSSOP14B						
	TC7MBL3126CFK	US14						
	TC7MBL3126CFT # †	TSSOP14B						
	TC7MBL3245CFK	US20	8				9 Ω @I _{is} = 30 mA	
TC7MBL3245CFT # †	TSSOP20B							
SPDT	TC7MBL3257CFK	US16	4	P-ch + N-ch	1.65 to 3.6 V	5 pF @V _{cc} = 3 V, A-port	8.5 Ω @I _{is} = 30 mA	10 μA @V _{cc} = 3.6 V
	TC7MBL3257CFT # †	TSSOP16B						
SP4T	TC7MBL3253CFK	US16	2	P-ch + N-ch	1.65 to 3.6 V	9 pF @V _{cc} = 3 V, A-port	9 Ω @I _{is} = 30 mA	10 μA @V _{cc} = 3.6 V
	TC7MBL3253CFT # †	TSSOP16B						

This device is compliant with the reliability requirements of AEC-Q100
 † Operation temperature is -40 to 125 °C

7-4 Level Shifters

Package Dimensions (unit: mm)

fsv (SOT-953)	UF6 (SOT-363F)	USV (SOT-353)	US8 (SOT-765)	US16	TSSOP16B	TSSOP48
						
1.0 x 1.0	2.0 x 2.1	2.0 x 2.1	2.0 x 3.1	4.0 x 4.0	5.0 x 6.4	12.5 x 8.1

Bus Buffer Type

Direction	Part Number	Package	Bit Count	Control Input	Function					
					Supply Voltage Range		Gate or Buffer	Sleep Mode	Low Noise	Series Resistor or Bus Hold
					V _{CCA} (V)	V _{CCB} (V)				
Bidirectional	TC7MP3125FK	US16	4	Active-Low (A side)	1.1 to 2.7	1.65 to 3.6	3-State Buffer	✓		
	TC7MP3125FT # †	TSSOP16B						✓		
	TC7MPN3125FK	US16						✓	✓	
	TC7MPN3125FT # †	TSSOP16B						✓	✓	
	74LVCT245FK ☆ †	US8	2	None	1.65 to 5.5	Buffer				
	74AVC4T245FT ★ †	TSSOP16B	4	Active-Low (A side)	0.8 to 3.6	3-State Buffer				Bus Hold
	74AVCH4T245FT ★ †									
	74AVC4T345FT ★ †									
	TC74VCX163245 †	TSSOP48	16	Active-Low (B side)	2.3 to 3.6	1.65 to 2.7	3-State Buffer			
	TC74VCX164245 †				1.65 to 2.7	2.3 to 3.6				
	TC74LCX163245 †				4.5 to 5.5	2.3 to 3.6			Series Resistor	
	TC74LCX164245 †									
TC74LCXR164245 †	2.3 to 3.6				4.5 to 5.5			Series Resistor		
Unidirectional	TC7SP3125TU	UF6	1	Active-Low (A side)	1.1 to 2.7	1.65 to 3.6	3-State Buffer	✓		
	TC7SPN3125TU							✓	✓	
	TC7WP3125FK †									
	TC7WPN3125FK †	US8	2	Active-Low (A side)				✓	✓	
	74LV4T125FT # †	TSSOP16B	4	Active-Low	1.65 to 5.5	(Single Supply)	3-State Buffer			
	74LV4T125FK †	US16								
	74LV4T126FT # †	TSSOP16B								
	74LV4T126FK †	US16								
	7UL1T00FS †	fsv	1	None	2.3 to 3.6	(Single Supply)	NAND			
	7UL1T02FS †							NOR		
	7UL1T04FS †							Inverter		
	7UL1T08FS †							AND		
	7UL1T32FS †							OR		
	7UL1T34FS †							Buffer		
	7UL1T86FS †							Exclusive-OR		
	7UL1T125FS †							3-State Buffer		
	7UL1T126FS †							NAND		
	7UL1T00FU †							NOR		
	7UL1T02FU †							Inverter		
	7UL1T04FU †							AND		
	7UL1T08FU †	OR								
	7UL1T32FU †	Buffer								
	7UL1T34FU †	Exclusive-OR								
	7UL1T86FU †	3-State Buffer								
7UL1T125FU †										
7UL1T126FU †										
	USV	1	None	2.3 to 3.6	(Single Supply)	NAND				
							NOR			
							Inverter			
							AND			
							OR			
							Buffer			
							Exclusive-OR			
							3-State Buffer			
							Active-Low			
							Active-High			

☆ New Products, ★ Under Development (The specification is subject to change without notice.)
 # This device is compliant with the reliability requirements of AEC-Q100
 † Operation temperature is -40 to 125 °C

- ① MOSFETs
- ② Tr./BRTs
- ③ Diodes
- ④ Power Management ICs
- ⑤ Linear ICs
- ⑥ Sensors
- ⑦ General Purpose Logic ICs
- ⑧ RF Devices
- ⑨ Packages

UF6 (SOT-363F)	US8 (SOT-765)	US14	US20	TSSOP14B	TSSOP20B	XSON6 (MP6D)
						
2.0 x 2.1	2.0 x 3.1	4.0 x 4.0	5.0 x 4.0	5.0 x 6.4	6.5 x 6.4	Bottom View 1.45 x 1.0

Bus Buffer Type

Direction	Part Number	Package	Bit Count	Control Input	Function						
					Supply Voltage Range		Gate or Buffer	Sleep Mode	Low Noise	Series Resistor or Bus Hold	
					V _{CCA} (V)	V _{CCB} (V)					
Unidirectional	7UL1T00NX ★ †	XSON6 (MP6D)	1	None	2.3 to 3.6	-	(Single Supply)	NAND			
	7UL1T02NX ★ †							NOR			
	7UL1T04NX ★ †							Inverter			
	7UL1T08NX ★ †							AND			
	7UL1T32NX ★ †							OR			
	7UL1T34NX ★ †							Buffer			
	7UL1T86NX ★ †							Exclusive-OR			
	7UL1T125NX ★ †							3-State Buffer			
	7UL1T126NX ★ †	Active-Low									
		Active-High									
	7UL2T00FK †	US8	2	None	2.3 to 3.6	-	(Single Supply)	NAND			
	7UL2T02FK †		3					NOR			
	7UL3T04FK †		2					Inverter			
	7UL2T08FK †		3					AND			
	7UL2T32FK †		2					OR			
	7UL3T34FK †		3					Buffer			
	7UL2T86FK †		2					Exclusive-OR			
	7UL2T125FK †		2					Active-Low			
7UL2T126FK †	Active-High										

Bus Switch Type

Switch function	Part Number	Package	Bit Count	Control Input	Specification			
					Supply Voltage Range		Switch I/O Capacitance @Switch OFF (typ.)	Switch ON Resistance @V _{CCA} = 3 V, V _{CCB} = 4.5 V, V _{IS} = 0 V (max)
					V _{CCA} (V)	V _{CCB} (V)		
SPST	TC7SPB9306TU	UF6	1	Active-High (A side)	1.65 to 5	2.3 to 5.5	7 pF @V _{CCA/B} = 3.3 V	8 Ω @I _{IS} = 30 mA
	TC7SPB9307TU			Active-Low (A side)				
	TC7WPB9306FK # †	US8	2	Active-High (A side)				
	TC7WPB9307FK # †			Active-Low (A side)				
	TC7QP9306FK	US14	4	Active-High (A side)				
	TC7QP9306FT # †	TSSOP14B		Active-Low (A side)				
	TC7QP9307FK	US14	8	Active-Low (A side)				
	TC7QP9307FT # †	TSSOP14B						
TC7MP9307FK	US20	8	Active-Low (A side)					
TC7MP9307FT # †	TSSOP20B							
SPDT	TC7MP9326FK	US14	2	Active-High (A side)	1.65 to 5	2.3 to 5.5	7 pF @V _{CCA/B} = 3.3 V	8 Ω @I _{IS} = 30 mA
	TC7MP9326FT # †	TSSOP14B		Active-Low (A side)				
	TC7MP9327FK	US14		Active-Low (A side)				
	TC7MP9327FT # †	TSSOP14B		Active-Low (A side)				

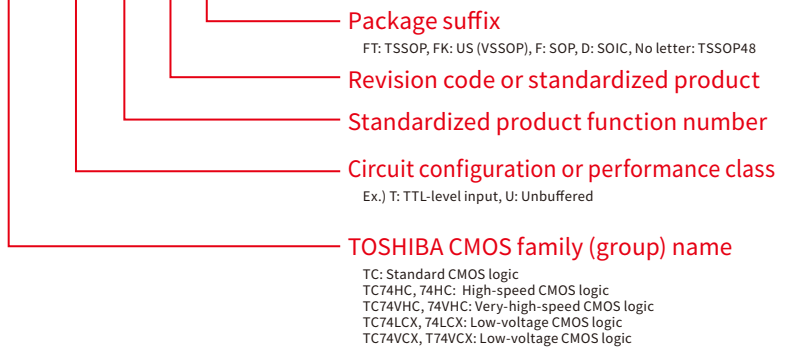
★ New Products, ★ Under Development (The specification is subject to change without notice.)

This device is compliant with the reliability requirements of AEC-Q100

† Operation temperature is -40 to 125 °C

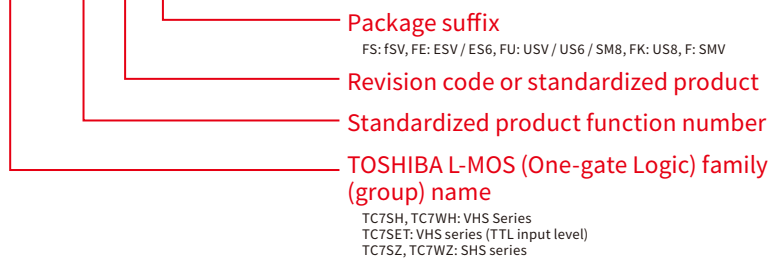
7-5 Part Naming Conventions Standard Logic

74VHC T 244 A FT

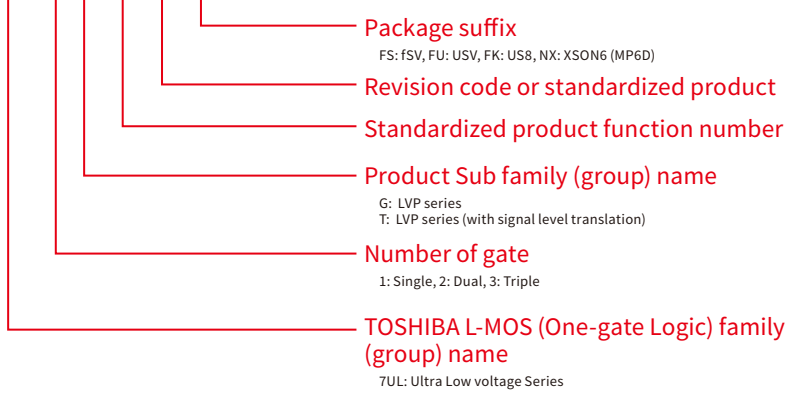


One-Gate Logic

TC7SZ 00 FS






7UL 1 G 00 FS



8. Radio-Frequency Devices

RF Diodes

Package Dimensions (unit: mm)

SOD-923	ESC (SOD-523)	USC (SOD-323)
		
1.0 x 0.6	1.6 x 0.8	2.5 x 1.25

Variable Capacitance Diodes

Application	Part Number	Structure	Package	Absolute Maximum Ratings	Electrical Characteristics (Ta = 25 °C)						
					V _R (V)	C _T upper (pF)	@V _R (V)	C _T lower (pF)	@V _R (V)	C _T upper / C _T lower	r _s typ. (Ω)
VCO	1SV285	Single	ESC	10	4.5	1	2	4	2.3	0.42	1
	1SV277	Single	USC	10	4.5	1	2	4	2.3	0.42	1
	1SV311	Single	ESC	10	9.7 to 11.1	1	4.45 to 5.45	4	2.1	0.28	1
	1SV310	Single	USC	10	9.7 to 11.1	1	4.45 to 5.45	4	2.1	0.28	1
	1SV281	Single	ESC	10	16	1	8	4	2	0.28	1
	1SV270	Single	USC	10	16	1	8	4	2	0.28	1
	1SV305	Single	ESC	10	18.3	1	6.1	4	3	0.27	1
	1SV304	Single	USC	10	18.3	1	6.1	4	3	0.27	1
	1SV323	Single	ESC	10	26.5 to 29.5	1	6 to 7.1	4	4.3	0.4	4
	1SV322	Single	USC	10	26.5 to 29.5	1	6 to 7.1	4	4.3	0.4	4
	1SV325	Single	ESC	10	44 to 49.5	1	9.2 to 12	4	4.3	0.4	4
	1SV324	Single	USC	10	44 to 49.5	1	9.2 to 12	4	4.3	0.4	4
	JDV2S36E	Single	ESC	10	44 to 49.5	1	5.4 to 7.3	6	7.5	0.4	4
	1SV280	Single	ESC	15	3.8 to 4.7	2	1.5 to 2	10	2.4	0.44	1
	JDV2S42FS ☆	Single	SOD-923	15	3.8 to 4.7	2	1.5 to 2	10	2.4	0.44	1
	1SV239	Single	USC	15	4.25	2	1.75	10	2.4	0.44	1
	1SV279	Single	ESC	15	14 to 16	2	5.5 to 6.5	10	2.5	0.2	5
	1SV229	Single	USC	15	14 to 16	2	5.5 to 6.5	10	2.5	0.2	5
JDV2S41AFS	Single	SOD-923	15	14 to 16	2	5.5 to 6.5	10	2.5	0.2	5	

☆ New Products

RF Diodes

Package Dimensions (unit: mm)

SL2 (SOD-962)	SOD-923	ESC (SOD-523)	USC (SOD-323)	VESM (SOT-723)	SSM (SOT-416)	USM (SOT-323)	S-Mini (SOT-346)
Bottom View 							
0.62 x 0.32	1.0 x 0.6	1.6 x 0.8	2.5 x 1.25	1.2 x 1.2	1.6 x 1.6	2.0 x 2.1	2.9 x 2.5

Schottky Barrier Diodes

Feature	Part Number	Structure	Package	Absolute Maximum Ratings		Electrical Characteristics (Ta = 25 °C)					
				V _R (V)	I _F (mA)	V _F typ. (V)	@I _F (mA)	I _R max (μA)	@V _R (V)	C _T typ. (pF)	@V _R (V)
Low V _F	JDH2S02SL	Single	SL2	10	10	0.24	1	25	0.5	0.25	0.2
	JDH2S02FS ☆	Single	SOD-923	10	10	0.24	1	25	0.5	0.25	0.2
Standard	1SS315	Single	USC	5	30	0.25	2	25	0.5	0.6	0.2
	1SS154	Single	S-Mini	6	30	0.5	10	0.5	5	0.8	0
	JDH3D01FV	Series	VESM	4	25	0.25	2	25	0.5	0.6	0.2
	JDH3D01S	Series	SSM	4	25	0.25	2	25	0.5	0.6	0.2
	1SS295	Series	S-Mini	4	30	0.25	2	25	0.5	0.6	0.2
	1SS271	Series	S-Mini	6	30	0.5	10	0.5	5	0.8	0

☆ New Products

Switching Diodes

Feature	Part Number	Structure	Package	Absolute Maximum Ratings		Electrical Characteristics (Ta = 25 °C)					
				V _R (V)	I _F (mA)	V _F typ. (V)	@I _F (mA)	C _T typ. (pF)	@V _R (V)	r _S typ. (Ω)	@I _F (mA)
Standard PIN diode	1SV308	Single	ESC	30	50	0.95	50	0.3	1	1	10
	1SV307	Single	USC	30	50	0.95	50	0.3	1	1	10
	JDP3C02AU	Cathode com.	USM	30	50	0.89	50	0.28	1	1	10
RF switching diode	1SS381	Single	ESC	30	100	0.85 (max)	2	0.7	6	0.6	2
	1SS314	Single	USC	30	100	0.85 (max)	2	0.7	6	0.5	2
	1SS364	Cathode com.	SSM	30	50	0.85 (max)	2	0.85	6	0.6	2
	1SS312	Cathode com.	USM	30	50	0.85 (max)	2	0.8	6	0.6	2
	1SS313	Anode com.	USM	30	50	0.85 (max)	2	0.8	6	0.6	2
	1SS268	Cathode com.	S-Mini	30	50	0.85 (max)	2	0.8	6	0.6	2
	1SS269	Anode com.	S-Mini	30	50	0.85 (max)	2	0.8	6	0.6	2

■ Part Naming Conventions

Radio-Frequency Diode (EIAJ registration products)

Ex.) 1 S S 381
 ① ② ③ ④

- ① The value that subtracted 1 from the total number of terminals
- ② S stands for Semiconductor
- ③ The kind of diode
 This section shows the kind of the Radio Frequency diode being used.
 (It is omitted in certain cases.)
 S: detection use, Frequency conversion use, and switching use
 V: variable capacitance diode, PIN diode
- ④ Serial number

Radio-Frequency Diode (EIAJ un-registration products)

Ex.) JD V 2 S 36 E
 ① ② ③ ④ ⑤ ⑥

- ① JD means High-frequency diode
- ② The kind of devices
 This section shows the kind of the devices being used.
 It is classified into H, P, S, and V by the devices being loaded.
 H: schottky barrier diode
 P: PIN diode
 S: band switching diode
 V: variable capacitance diode
- ③ The number of terminals
- ④ Internal connection
 This section shows the kind of the internal connection of a product.
 S: single
 C: cathode common
 P: parallel
- ⑤ Serial number
- ⑥ Package type

AU	USM
S	SSM
E	ESC
SL	SL2
FV	VESM
FS, AFS	SOD-923

9. Device Packages

2 Pin packages

SL2 (SOD-962) (0.62 x 0.32)	CL2E (1.0 x 0.6)	SOD-923 (1.0 x 0.6)
<p>Package dimension unit : mm</p>	<p>Package dimension unit : mm</p>	<p>Package dimension unit : mm</p>
<p>Land pattern example unit : mm</p>	<p>Land pattern example unit : mm</p>	<p>Land pattern example unit : mm</p>
CST2 (SOD-882) (1.0 x 0.6)	CST2B (1.2 x 0.8)	CST2C (SOD-963) (1.6 x 0.8)
<p>Package dimension unit : mm</p>	<p>Package dimension unit : mm</p>	<p>Package dimension unit : mm</p>
<p>Land pattern example unit : mm</p>	<p>Land pattern example unit : mm</p>	<p>Land pattern example unit : mm</p>
ESC (SOD-523) (1.6 x 0.8)	USC (SOD-323) (2.5 x 1.25)	US2H (SOD-323HE) (2.5 x 1.4)
<p>Package dimension unit : mm</p>	<p>Package dimension unit : mm</p>	<p>Package dimension unit : mm</p>
<p>Land pattern example unit : mm</p>	<p>Land pattern example unit : mm</p>	<p>Land pattern example unit : mm</p>

3 Pin packages

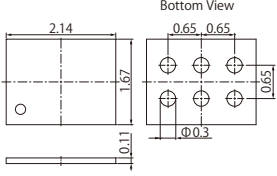
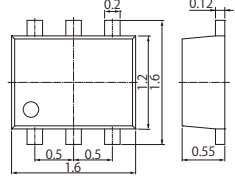
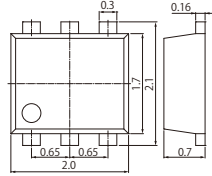
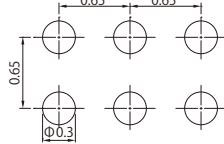
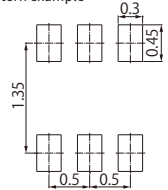
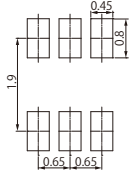
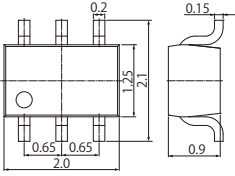
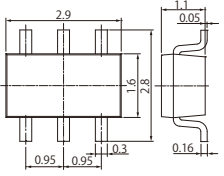
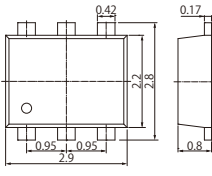
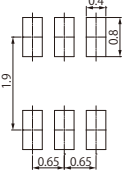
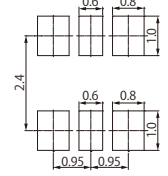
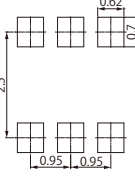
<p>CST3C (0.8 x 0.6)</p> <p>Package dimension unit: mm</p> <p>Land pattern example unit: mm</p>	<p>CST3 (SOT-883) (1.0 x 0.6)</p> <p>Package dimension unit: mm</p> <p>Land pattern example unit: mm</p>	<p>VESM (SOT-723) (1.2 x 1.2)</p> <p>Package dimension unit: mm</p> <p>Land pattern example unit: mm</p>
<p>SSM (SOT-416) (1.6 x 1.6)</p> <p>Package dimension unit: mm</p> <p>Land pattern example unit: mm</p>	<p>USM (SOT-323) (2.0 x 2.1)</p> <p>Package dimension unit: mm</p> <p>Land pattern example unit: mm</p>	<p>UFM (SOT-323F) (2.0 x 2.1)</p> <p>Package dimension unit: mm</p> <p>Land pattern example unit: mm</p>
<p>S-Mini (SOT-346) (2.9 x 2.5)</p> <p>Package dimension unit: mm</p> <p>Land pattern example unit: mm</p>	<p>SOT23 (SOT-23) (2.9 x 2.4)</p> <p>Package dimension unit: mm</p> <p>Land pattern example unit: mm</p>	<p>SOT-23F (2.9 x 2.4)</p> <p>Package dimension unit: mm</p> <p>Land pattern example unit: mm</p>

4 Pin packages

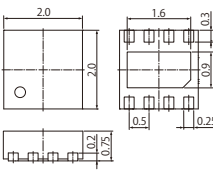
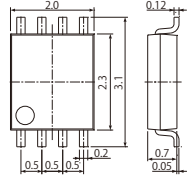
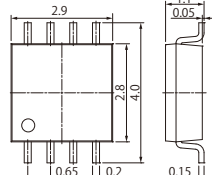
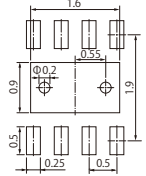
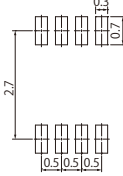
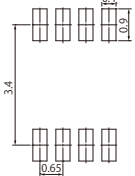
<p>WCSP4E (0.645 x 0.645)</p> <p>Package dimension unit : mm</p>	<p>WCSP4F (0.645 x 0.645)</p> <p>Package dimension unit : mm</p>	<p>WCSP4G (0.645 x 0.645)</p> <p>Package dimension unit : mm</p>
<p>Land pattern example unit : mm</p>	<p>Land pattern example unit : mm</p>	<p>Land pattern example unit : mm</p>
<p>WCSP4D (0.79 x 0.79)</p> <p>Package dimension unit : mm</p>	<p>SDFN4E (0.8 x 0.8)</p> <p>Package dimension unit : mm</p>	<p>WCSP4C (0.9 x 0.9)</p> <p>Package dimension unit : mm</p>
<p>Land pattern example unit : mm</p>	<p>Land pattern example unit : mm</p>	<p>Land pattern example unit : mm</p>
<p>DFN4D (1.0 x 1.0)</p> <p>Package dimension unit : mm</p>	<p>DFN4E (1.0 x 1.0)</p> <p>Package dimension unit : mm</p>	<p>DFN4F (1.0 x 1.0)</p> <p>Package dimension unit : mm</p>
<p>Land pattern example unit : mm</p>	<p>Land pattern example unit : mm</p>	<p>Land pattern example unit : mm</p>

<p>WCSP6F (1.2 x 0.8)</p> <p>Package dimension unit : mm</p>	<p>WCSP6G (1.2 x 0.8)</p> <p>Package dimension unit : mm</p>	<p>DFN6 (1.25 x 1.0)</p> <p>Package dimension unit : mm</p>
<p>Land pattern example unit : mm</p>	<p>Land pattern example unit : mm</p>	<p>Land pattern example unit : mm</p>
<p>MP6C (1.45 x 1.0)</p> <p>Package dimension unit : mm</p>	<p>XSON6(MP6D) (1.45 x 1.0)</p> <p>Package dimension unit : mm</p>	<p>WCSP6C (1.5 x 1.0)</p> <p>Package dimension unit : mm</p>
<p>Land pattern example unit : mm</p>	<p>Land pattern example unit : mm</p>	<p>Land pattern example unit : mm</p>
<p>DFN2020(WF) (2.0 x 2.0)</p> <p>Package dimension unit : mm</p>	<p>UDFN6 (SOT-1118) (2.0 x 2.0)</p> <p>Package dimension unit : mm</p>	<p>UDFN6B (SOT-1220) (2.0 x 2.0)</p> <p>Package dimension unit : mm</p>
<p>Land pattern example unit : mm</p>	<p>Land pattern example unit : mm</p>	<p>Land pattern example unit : mm</p>

6 Pin packages

TCSP6A-172101 (2.14 x 1.67)		ES6 (SOT-563) (1.6 x 1.6)		UF6 (SOT-363F) (2.0 x 2.1)	
Package dimension unit: mm		Package dimension unit: mm		Package dimension unit: mm	
Land pattern example unit: mm		Land pattern example unit: mm		Land pattern example unit: mm	
US6 (SOT-363) (2.0 x 2.1)		SM6 (SOT-26) (2.9 x 2.8)		TSOP6F (2.9 x 2.8)	
Package dimension unit: mm		Package dimension unit: mm		Package dimension unit: mm	
Land pattern example unit: mm		Land pattern example unit: mm		Land pattern example unit: mm	

8 Pin packages

WSO8 (2.0 x 2.0)		US8 (SOT-765) (2.0 x 3.1)		SM8 (SOT-505) (2.9 x 4.0)	
Package dimension unit: mm		Package dimension unit: mm		Package dimension unit: mm	
Land pattern example unit: mm		Land pattern example unit: mm		Land pattern example unit: mm	

9 Pin packages

WCSP9 (1.5 x 1.5)
<p>Package dimension unit : mm</p>
<p>Land pattern example unit : mm</p>

DFN10 (2.5 x 1.0)
<p>Package dimension unit : mm</p>
<p>Land pattern example unit : mm</p>

TCSPAC-153001 (2.98 x 1.49)
<p>Package dimension unit : mm</p>
<p>Land pattern example unit : mm</p>

TCSPAG-341501 (3.37 x 1.47)
<p>Package dimension unit : mm</p>
<p>Land pattern example unit : mm</p>

UQFN10B (1.4 x 1.8)
<p>Package dimension unit : mm</p>
<p>Land pattern example unit : mm</p>

WSON10 (3.0 x 3.0)
<p>Package dimension unit : mm</p>
<p>Land pattern example unit : mm</p>

14 Pin packages

WSON10B (3.0 x 3.0)
<p>Package dimension unit : mm</p>
<p>Land pattern example unit : mm</p>

TCSPED-302701 (3.0 x 2.74)
<p>Package dimension unit : mm</p>
<p>Land pattern example unit : mm</p>

US14 (4.0 x 4.0)
<p>Package dimension unit : mm</p>
<p>Land pattern example unit : mm</p>

16 Pin packages

SOIC16 (9.9 x 6.0)	SOP16 (10.3 x 7.8)	TQFN20 (4.5 x 2.5)
<p>Package dimension unit : mm</p>	<p>Package dimension unit : mm</p>	<p>Package dimension unit : mm</p> <p>Bottom View</p>
<p>Land pattern example unit : mm</p>	<p>Land pattern example unit : mm</p>	<p>Land pattern example unit : mm</p>

US20 (5.0 x 4.0)	TSSOP20 (6.5 x 6.4)	TSSOP20B (6.5 x 6.4)
<p>Package dimension unit : mm</p>	<p>Package dimension unit : mm</p>	<p>Package dimension unit : mm</p>
<p>Land pattern example unit : mm</p>	<p>Land pattern example unit : mm</p>	<p>Land pattern example unit : mm</p>

48 Pin packages

SOIC20 (12.8 x 10.3)	SOP20 (12.8 x 7.8)	TSSOP48 (12.5 x 8.1)
<p>Package dimension unit : mm</p>	<p>Package dimension unit : mm</p>	<p>Package dimension unit : mm</p>
<p>Land pattern example unit : mm</p>	<p>Land pattern example unit : mm</p>	<p>Land pattern example unit : mm</p>

RESTRICTIONS ON PRODUCT USE

Toshiba Corporation and its subsidiaries and affiliates are collectively referred to as "TOSHIBA". Hardware, software and systems described in this document are collectively referred to as "Product".

- TOSHIBA reserves the right to make changes to the information in this document and related Product without notice.
- This document and any information herein may not be reproduced without prior written permission from TOSHIBA. Even with TOSHIBA's written permission, reproduction is permissible only if reproduction is without alteration/omission.
- Though TOSHIBA works continually to improve Product's quality and reliability, Product can malfunction or fail. Customers are responsible for complying with safety standards and for providing adequate designs and safeguards for their hardware, software and systems which minimize risk and avoid situations in which a malfunction or failure of Product could cause loss of human life, bodily injury or damage to property, including data loss or corruption. Before customers use the Product, create designs including the Product, or incorporate the Product into their own applications, customers must also refer to and comply with (a) the latest versions of all relevant TOSHIBA information, including without limitation, this document, the specifications, the data sheets and application notes for Product and the precautions and conditions set forth in the "TOSHIBA Semiconductor Reliability Handbook" and (b) the instructions for the application with which the Product will be used with or for. Customers are solely responsible for all aspects of their own product design or applications, including but not limited to (a) determining the appropriateness of the use of this Product in such design or applications; (b) evaluating and determining the applicability of any information contained in this document, or in charts, diagrams, programs, algorithms, sample application circuits, or any other referenced documents; and (c) validating all operating parameters for such designs and applications. **TOSHIBA ASSUMES NO LIABILITY FOR CUSTOMERS' PRODUCT DESIGN OR APPLICATIONS.**
- **PRODUCT IS NEITHER INTENDED NOR WARRANTED FOR USE IN EQUIPMENTS OR SYSTEMS THAT REQUIRE EXTRAORDINARILY HIGH LEVELS OF QUALITY AND/OR RELIABILITY, AND/OR A MALFUNCTION OR FAILURE OF WHICH MAY CAUSE LOSS OF HUMAN LIFE, BODILY INJURY, SERIOUS PROPERTY DAMAGE AND/OR SERIOUS PUBLIC IMPACT ("UNINTENDED USE").** Except for specific applications as expressly stated in this document, Unintended Use includes, without limitation, equipment used in nuclear facilities, equipment used in the aerospace industry, lifesaving and/or life supporting medical equipment, equipment used for automobiles, trains, ships and other transportation, traffic signaling equipment, equipment used to control combustions or explosions, safety devices, elevators and escalators, and devices related to power plant. **IF YOU USE PRODUCT FOR UNINTENDED USE, TOSHIBA ASSUMES NO LIABILITY FOR PRODUCT.** For details, please contact your TOSHIBA sales representative or contact us via our website.
- Do not disassemble, analyze, reverse-engineer, alter, modify, translate or copy Product, whether in whole or in part.
- Product shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable laws or regulations.
- The information contained herein is presented only as guidance for Product use. No responsibility is assumed by TOSHIBA for any infringement of patents or any other intellectual property rights of third parties that may result from the use of Product. No license to any intellectual property right is granted by this document, whether express or implied, by estoppel or otherwise.
- **ABSENT A WRITTEN SIGNED AGREEMENT, EXCEPT AS PROVIDED IN THE RELEVANT TERMS AND CONDITIONS OF SALE FOR PRODUCT, AND TO THE MAXIMUM EXTENT ALLOWABLE BY LAW, TOSHIBA (1) ASSUMES NO LIABILITY WHATSOEVER, INCLUDING WITHOUT LIMITATION, INDIRECT, CONSEQUENTIAL, SPECIAL, OR INCIDENTAL DAMAGES OR LOSS, INCLUDING WITHOUT LIMITATION, LOSS OF PROFITS, LOSS OF OPPORTUNITIES, BUSINESS INTERRUPTION AND LOSS OF DATA, AND (2) DISCLAIMS ANY AND ALL EXPRESS OR IMPLIED WARRANTIES AND CONDITIONS RELATED TO SALE, USE OF PRODUCT, OR INFORMATION, INCLUDING WARRANTIES OR CONDITIONS OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, ACCURACY OF INFORMATION, OR NONINFRINGEMENT.**
- Do not use or otherwise make available Product or related software or technology for any military purposes, including without limitation, for the design, development, use, stockpiling or manufacturing of nuclear, chemical, or biological weapons or missile technology products (mass destruction weapons). Product and related software and technology may be controlled under the applicable export laws and regulations including, without limitation, the Japanese Foreign Exchange and Foreign Trade Law and the U.S. Export Administration Regulations. Export and re-export of Product or related software or technology are strictly prohibited except in compliance with all applicable export laws and regulations.
- Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. Please use in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. **TOSHIBA ASSUMES NO LIABILITY FOR DAMAGES OR LOSSES OCCURRING AS A RESULT OF NONCOMPLIANCE WITH APPLICABLE LAWS AND REGULATIONS.**

TOSHIBA

Toshiba Electronic Devices & Storage Corporation
Toshiba Electronic Device Solutions Corporation

<https://toshiba.semicon-storage.com/>